

Dielectric-Loaded Accelerating (DLA) Structures

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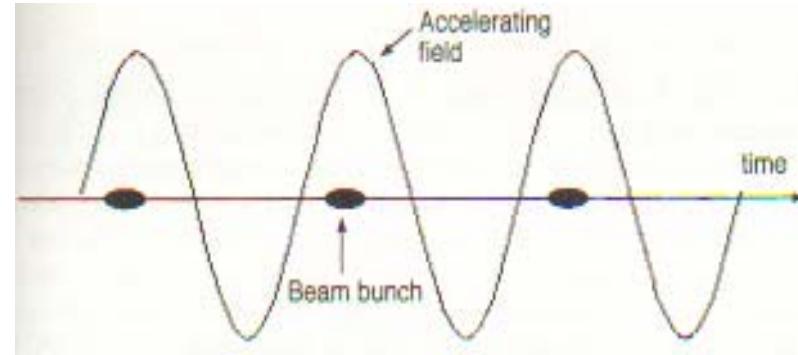
Contents

- Why Dielectric-Loaded Accelerating Structure?
 - ____ theory, varieties, history, etc.
- How to Make it?
 - ____ EM simulation, engineering design, fabrication, etc.
- Does It Work Well?
 - ____ challenges found out of the experiments.
- More advanced topics
 - ____ multipactor suppression, multilayered DLA, transverse mode damping, frequency tuning, etc.

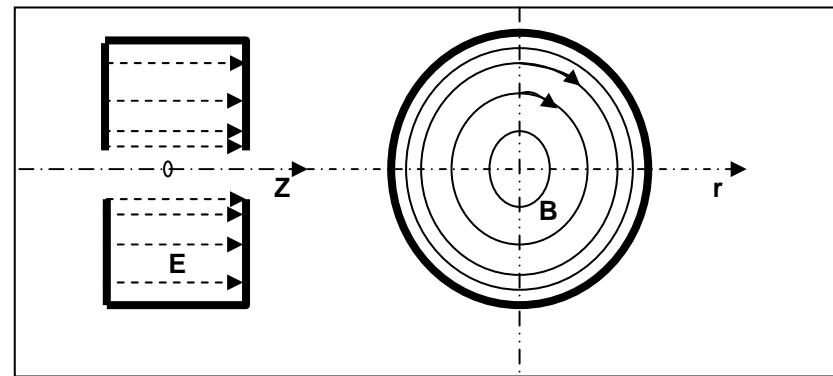
Part I: Why Dielectric-Loaded Accelerating Structure? --- theory, history, varieties, etc.

RF Driven Linear Accelerator

Using a sinusoidally varying electric field for acceleration, particle can either gain or lose energy, depending on the beam phase relative to the crest of the wave. (synchronization)



The electric and magnetic field pattern in a simple cylindrical cavity operated in a TM mode. Such a mode is characterized by a longitudinal electric field on axis, which is ideal for acceleration of a charged particle beam.



Resonant linear accelerators are usually single-pass machines. Charged particles traverse each section only once; therefore, the kinetic energy of the beam is limited by the length of the accelerator. Strong accelerating electric fields are desirable to achieve the maximum kinetic energy in the shortest length.

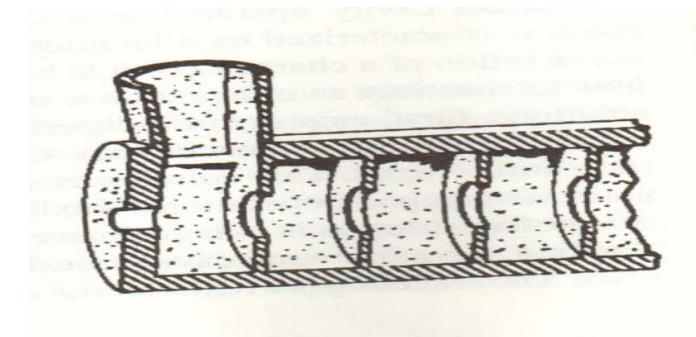
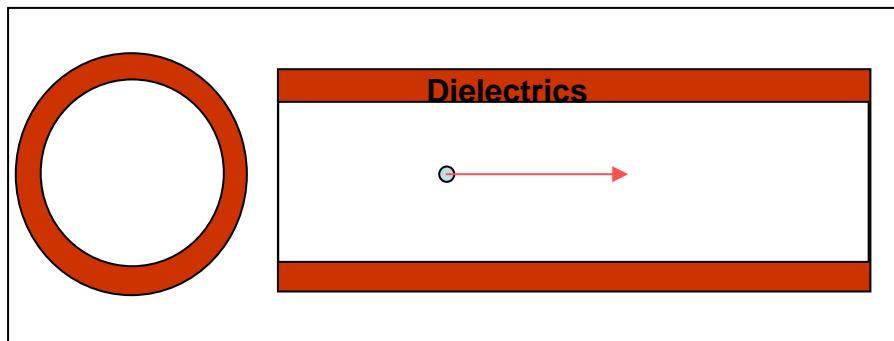
Want: Maximum accelerating gradient for a given RF power input.

***Dielectric loaded waveguide can slow the RF wave for acceleration.**

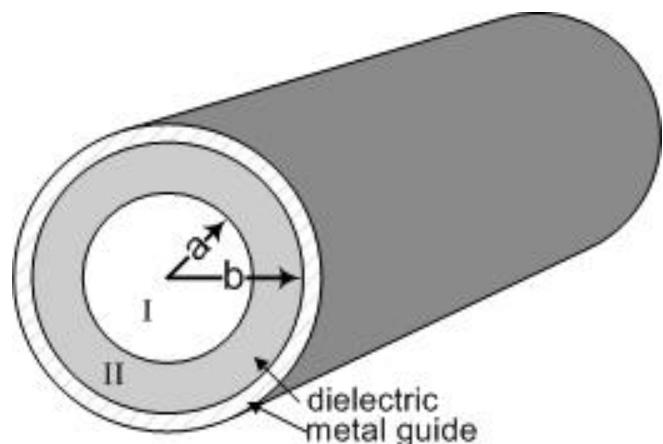
***Low-loss dielectric materials bring promise to this kind of structure.**

- Advantages: simplicity of fabrication
potentially higher breakdown threshold
Easy deflecting mode damping
- Challenges: multipactor, broadband coupling

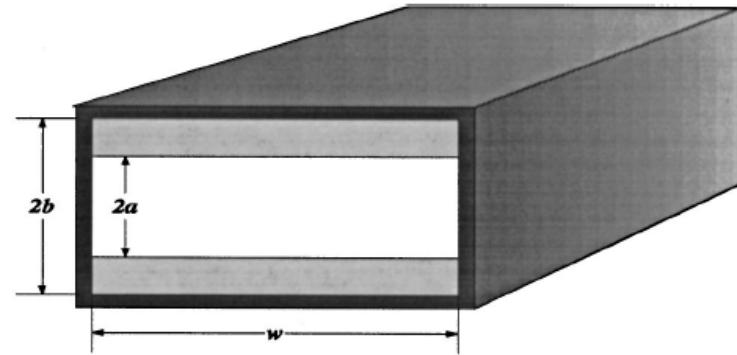
$$v_g v_p = \frac{1}{\mu \epsilon}$$



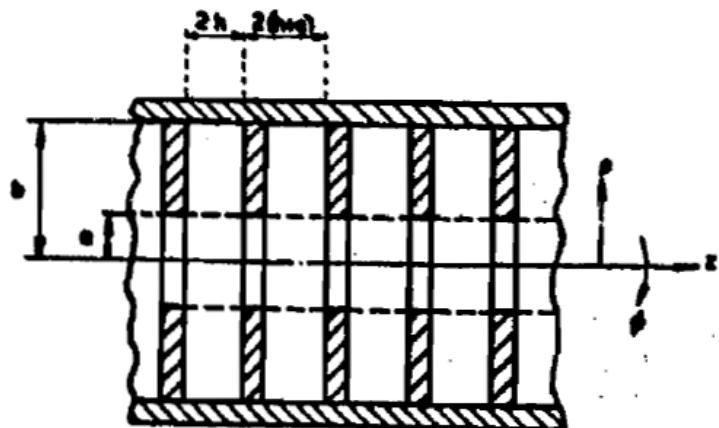
Geometrical Varieties:



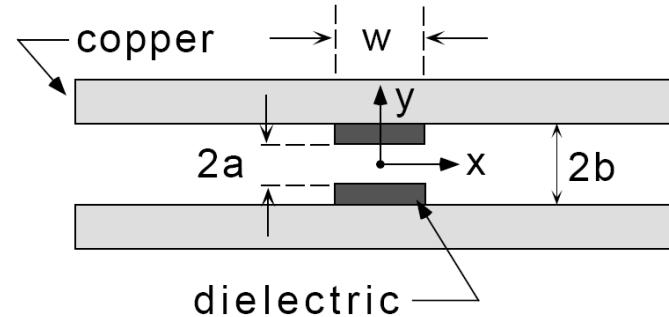
[ref1] Flesher, G., and G. Cohn. "Dielectric Loading for Waveguide Linear Accelerators." *AIEE Transactions* 70 (1951):887-93.



[ref2] Xiao, L., W. Gai, and X. Sun, "Field Analysis of a Dielectric-loaded Rectangular Waveguide accelerating Structure." *Physical Review E* 65 (2001): 016505.

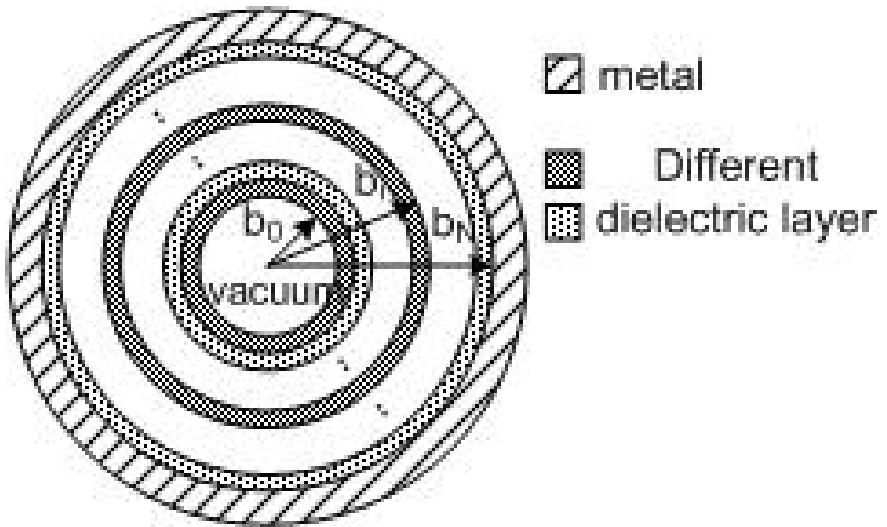


[ref3]. R.B. R.-Shersby-Harvie,etc., *Proc. I.E.E. B.*, 104 (1957) 273



[ref4] Marc E. Hill, SLAC-R-560 (2000).

A little bit of EM theory of a general case



General solutions of longitudinal component of electric and magnetic fields for the i^{th} dielectric layer are:

$$E_{zi}(z, r, \phi) = [A_i J_n(k_i r) + B_i Y_n(k_i r)] e^{jn\phi} e^{j(\omega t - \beta z)}$$

$$H_{zi}(z, r, \phi) = [C_i J_n(k_i r) + D_i Y_n(k_i r)] e^{jn\phi} e^{j(\omega t - \beta z)}$$

Refer to D. Pozar's
Microwave
Engineering (page
117-126), or any
other EM textbook.

$$k_i = \omega \sqrt{\frac{\mu_{ri} \epsilon_{ri}}{c^2} - \frac{1}{v_p^2}}$$

$$\beta^2 = \omega^2 \mu_0 \mu_{ri} \epsilon_{ri} - k_i^2$$

v_p is the phase velocity of the wave, c is speed of light in vacuum,
 k_i is the transverse wave number in the i^{th} layer,
 β is the propagation constant along the z axis, and
 $\mu_{ri} \epsilon_{ri}$ are the relative permeability and permittivity for the i^{th} layer respectively.

In a
homogenous
waveguide

$$E_{ri} = \frac{-j}{k_i^2} \left(\beta \frac{\partial E_{zi}}{\partial r} + \frac{\omega \mu_i}{r} \frac{\partial H_{zi}}{\partial \phi} \right)$$

$$E_{\phi i} = \frac{-j}{k_i^2} \left(\beta \frac{\partial E_{zi}}{\partial \phi} - \omega \mu_i \frac{\partial H_{zi}}{\partial r} \right)$$

$$H_{ri} = \frac{j}{k_i^2} \left(\frac{\omega \epsilon_i}{r} \frac{\partial E_{zi}}{\partial \phi} - \beta \frac{\partial H_{zi}}{\partial r} \right)$$

$$H_{\phi i} = \frac{-j}{k_i^2} \left(\omega \epsilon_i \frac{\partial E_{zi}}{\partial r} + \frac{\beta}{r} \frac{\partial H_{zi}}{\partial \phi} \right)$$

B.C. $\rightarrow E_z$ and H_z
continuous at the
boundary
between the
neighbor layers

recurrence relation from the i th layer to the $(i+1)$ th layer

$$\begin{pmatrix} A_{i+1} \\ B_{i+1} \\ C_{i+1} \\ D_{i+1} \end{pmatrix} = M \begin{pmatrix} A_i \\ B_i \\ C_i \\ D_i \end{pmatrix} \quad , i = 0, \dots, N$$

M is transfer matrix between neighbor layers ⁸

Transfer matrix M

$$M = \begin{pmatrix} Y_n'(k_i r) J_n(k_i r) - \frac{k_{i+1} \epsilon_i}{k_i \epsilon_{i+1}} Y_n(k_{i+1} r) J_n'(k_i r) & Y_n'(k_{i+1} r) Y_n(k_i r) - \frac{k_{i+1} \epsilon_i}{k_i \epsilon_{i+1}} Y_n(k_{i+1} r) Y_n'(k_i r) & \frac{\beta}{\omega \epsilon_{i+1}} \left(\frac{1}{k_{i+1} r} - \frac{k_{i+1}}{k_i^2 r} \right) J_n(k_i r) Y_n(k_{i+1} r) & \frac{\beta}{\omega \epsilon_{i+1}} \left(\frac{1}{k_{i+1} r} - \frac{k_{i+1}}{k_i^2 r} \right) Y_n(k_i r) Y_n(k_{i+1} r) \\ \frac{k_{i+1} \epsilon_i}{k_i \epsilon_{i+1}} J_n'(k_i r) J_n(k_{i+1} r) - J_n'(k_{i+1} r) J_n(k_i r) & \frac{k_{i+1} \epsilon_i}{k_i \epsilon_{i+1}} J_n(k_{i+1} r) Y_n'(k_i r) - J_n'(k_{i+1} r) Y_n(k_i r) & \frac{\beta}{\omega \epsilon_{i+1}} \left(\frac{k_{i+1}}{k_i^2 r} - \frac{1}{k_{i+1} r} \right) J_n(k_i r) J_n(k_{i+1} r) & \frac{\beta}{\omega \epsilon_{i+1}} \left(\frac{k_{i+1}}{k_i^2 r} - \frac{1}{k_{i+1} r} \right) J_n(k_i r) Y_n(k_i r) \\ \frac{\beta}{\omega \mu_{i+1}} \left(\frac{1}{k_{i+1} r} - \frac{k_{i+1}}{k_i^2 r} \right) Y_n(k_{i+1} r) J_n(k_i r) & \frac{\beta}{\omega \mu_{i+1}} \left(\frac{1}{k_{i+1} r} - \frac{k_{i+1}}{k_i^2 r} \right) Y_n(k_i r) Y_n(k_{i+1} r) & J_i(k_i r) Y_i'(k_{i+1} r) - \frac{k_{i+1} \mu_i}{k_i \mu_{i+1}} J_n(k_i r) Y_n(k_{i+1} r) & Y_n(k_i r) Y_n'(k_{i+1} r) - \frac{k_{i+1} \mu_i}{k_i \mu_{i+1}} Y_n(k_{i+1} r) Y_n'(k_i r) \\ \frac{\beta}{\omega \mu_{i+1}} \left(\frac{k_{i+1}}{k_i^2 r} - \frac{1}{k_{i+1} r} \right) J_n(k_i r) J_n(k_{i+1} r) & \frac{\beta}{\omega \mu_{i+1}} \left(\frac{k_{i+1}}{k_i^2 r} - \frac{1}{k_{i+1} r} \right) Y_n(k_i r) J_n(k_{i+1} r) & \frac{k_{i+1} \mu_i}{k_i \mu_{i+1}} J_n(k_{i+1} r) J_n'(k_i r) - J_n'(k_{i+1} r) J_n(k_i r) & \frac{k_{i+1} \mu_i}{k_i \mu_{i+1}} J_n(k_{i+1} r) Y_n'(k_i r) - J_n'(k_{i+1} r) Y_n(k_i r) \end{pmatrix}$$

Where, J_n , Y_n , J_n' , Y_n' are n^{th} order Bessel functions and their derivatives.

k_i , k_{i+1} transverse cut-off wave number in i^{th} and $i+1^{th}$ respectively.

N-layer structure with metal jacket

$$\begin{pmatrix} A_N \\ B_N \\ C_N \\ D_N \end{pmatrix} = M_{N-1} \cdots M_1 M_0 \begin{pmatrix} A_0 \\ 0 \\ C_0 \\ 0 \end{pmatrix}$$

Reality tells us
that B_0 and D_0
have to be Zeros.

with

$E_z=0$ & $H_r=0$
@metal surface

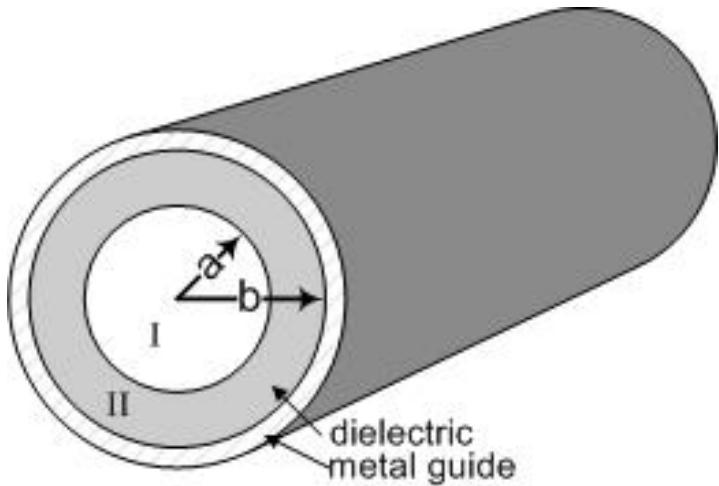


$$\left\{ \begin{array}{l} A_N J_n'(k_N b_N) + B_N Y_n'(k_N b_N) = 0 \\ C_N J_n(k_N b_N) + D_N Y_n(k_N b_N) = 0 \end{array} \right.$$



The conditions for a non-trivial solution of the above equations will determine the dispersion relation of this waveguide.

Now, it comes to what we care most:



$$E_z = \begin{cases} B_1 J_0(k_1 r) e^{j(\omega t - \beta z)} & 0 \leq r < a \\ B_2 [F_{00}(k_2 r)] e^{j(\omega t - \beta z)} & a \leq r \leq b \end{cases}$$

$$E_r = \begin{cases} -\frac{j\beta}{k_1} B_1 J_0'(k_1 r) e^{j(\omega t - \beta z)} & 0 \leq r < a \\ -\frac{j\beta}{k_2} B_2 F_{00}'(k_2 r) e^{j(\omega t - \beta z)} & a < r \leq b \end{cases}$$

$$H_\phi = \begin{cases} -\frac{j\omega\epsilon_0}{k_1} B_1 J_0'(k_1 r) e^{j(\omega t - \beta z)} & 0 \leq r < a \\ -\frac{j\omega\epsilon_r\epsilon_0}{k_2} B_2 F_{00}'(k_2 r) e^{j(\omega t - \beta z)} & a < r \leq b \end{cases}$$

Fields components and dispersion relation
for TM01 mode in a single layer dielectric-
loaded structure

$$k_1 = \omega \sqrt{\frac{1}{c^2} - \frac{1}{v_p^2}}$$

$$k_2 = \omega \sqrt{\frac{\epsilon_r}{c^2} - \frac{1}{v_p^2}}$$

$$\beta^2 = k_0^2 - k_1^2 = \epsilon_r k_0^2 - k_2^2$$

$$k_0^2 = \omega^2 \mu_0 \epsilon_0$$

$$\left[\frac{1}{k_1} \frac{J_0'(k_1 a)}{J_0(k_1 a)} - \frac{\epsilon_r}{k_2} \frac{F_{00}'(k_2 a)}{F_{00}(k_2 a)} \right] = 0$$

where

$$F_{00}(k_2 a) = J_0(k_2 a) - \frac{J_0(k_2 b)}{Y_0(k_2 b)} Y_0(k_2 a)$$

$$F_{00}'(k_2 a) = J_0'(k_2 a) - \frac{J_0'(k_2 b)}{Y_0'(k_2 b)} Y_0'(k_2 a)$$

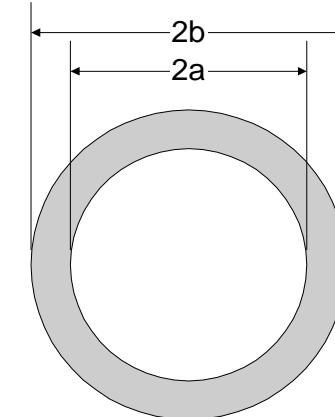
Example:

The operation frequency: $f=11.424\text{GHz}$

The dielectric constant of ceramic is 20

The inner radius of dielectric ceramic: $a=3\text{mm}$

The phase velocity of TM_{01} mode: $v_p=c$.

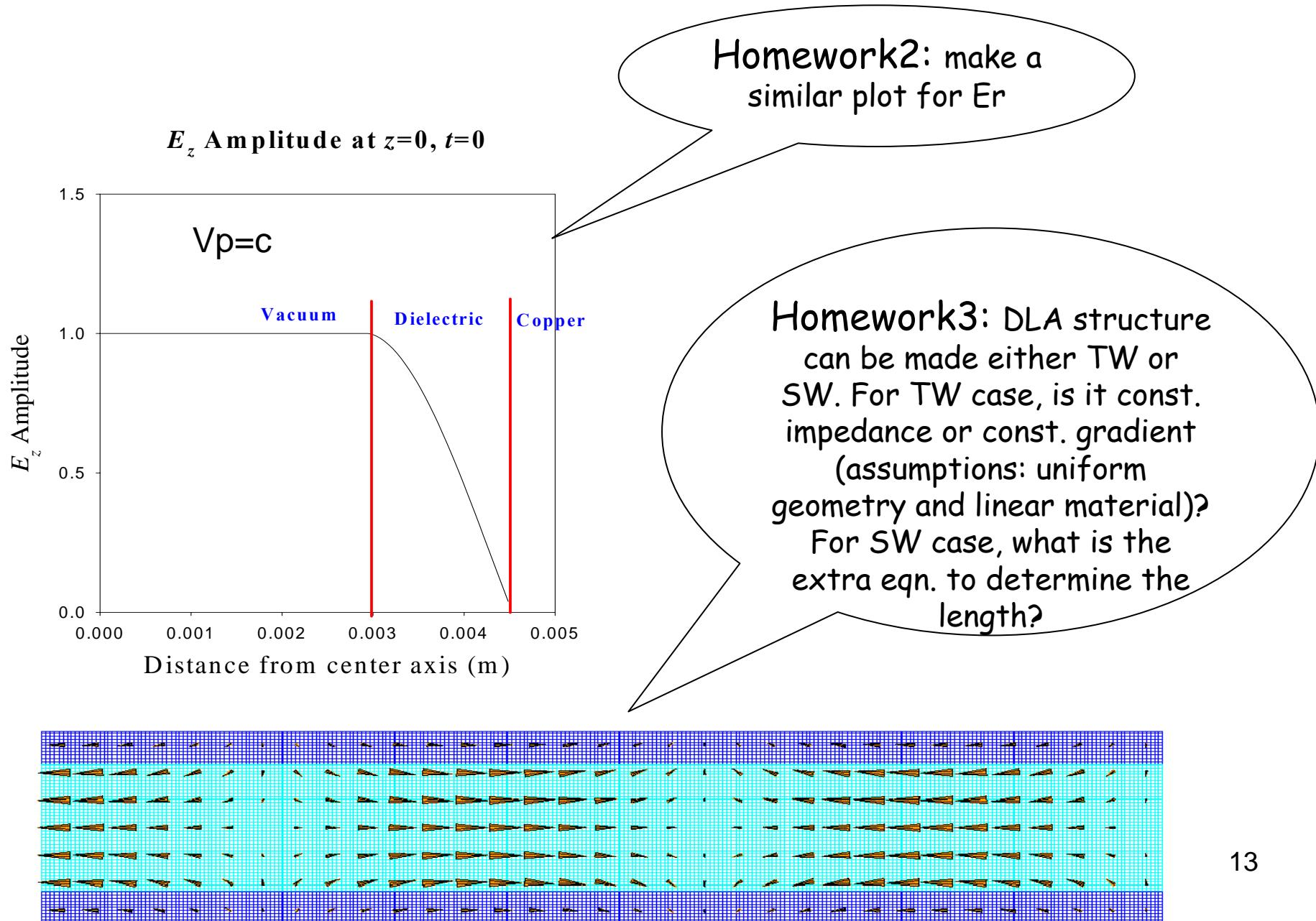


Using the equations of TM_{01} mode, the solution of the outer radius b of dielectric ceramic can be found

$b=4.56\text{mm}$.

Homework1: if $a=2\text{mm}$, what is the b ? (You may use Matlab/MathCAD to solve the dispersion relation, or use CST MWS)

Field Pattern Inside the Dielectric-lined Waveguide



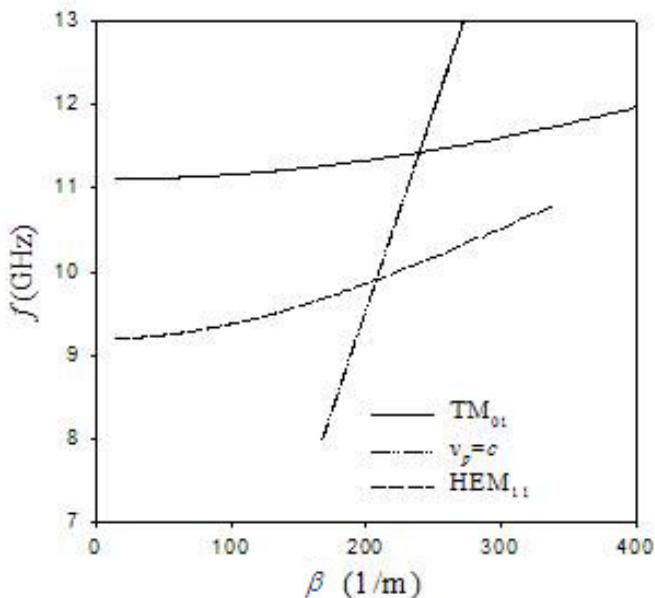
Dispersion Curves

The general dispersion relation

$$\left[\frac{\mu_0}{k_1 a} \frac{J_n'(k_1 a)}{J_n(k_1 a)} - \frac{\mu_0}{k_2 a} \frac{G_{nn}'(k_2 a)}{G_{nn}(k_2 a)} \right] \left[\frac{\epsilon_0}{k_1 a} \frac{J_n'(k_1 a)}{J_n(k_1 a)} - \frac{\epsilon_r \epsilon_0}{k_2 a} \frac{F_{nn}'(k_2 a)}{F_{nn}(k_2 a)} \right]$$
$$= \frac{(\beta n \omega)^2}{(k_1 k_2 a)^4} (\mu_0 \epsilon_r \epsilon_0 - \mu_0 \epsilon_0)^2$$

The dispersion curves of TM_{01} mode and HEM_{11} mode

β vs. Frequency for TM_{01} and HEM_{11} modes



Homework4: make
a similar plot use
CST MWS for a
comparison

Acceleration Parameters

You know the field expressions.
You can calculate everything.

$$\left\{ \begin{array}{l} P = \frac{1}{2} \oint_S \vec{E} \times \vec{H}^* \cdot d\vec{s} \\ U = \frac{\epsilon}{4} \operatorname{Re} \left(\int_V \vec{E} \times \vec{E}^* dv \right) + \frac{\mu}{4} \operatorname{Re} \left(\int_V \vec{H} \times \vec{H}^* dv \right) \end{array} \right.$$

$$Q = \frac{\omega U}{P_{loss}}$$

$$P_{loss} = \frac{R_s}{2} \int_S |H_\perp|_{r=b}^2 ds + \frac{1}{2} \int_{\substack{\text{Dielectric} \\ \text{UnitLength}}} \omega \epsilon_r \epsilon_0 \tan \delta_l E^2 dV$$

$$R_s = \sqrt{\frac{\mu_0 \omega}{2\sigma}}$$



$$\left\{ \begin{array}{l} v_g = \frac{d\omega}{d\beta} = \frac{P}{U} \\ \frac{r}{Q} = \frac{E_a^2}{\omega U} \\ r = \frac{E_a^2}{-dP/dz} \\ \alpha_0 = \frac{\omega}{2Qv_g} \end{array} \right.$$

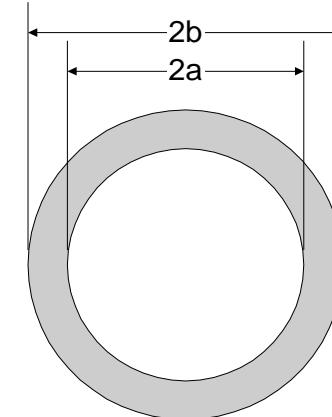
Example:

The operation frequency: $f=11.424\text{GHz}$

The dielectric constant of ceramic is 20, no loss

The inner radius of dielectric ceramic: $a= 3\text{mm}$

$b=4.567\text{mm}$.



PARAMETERS	MgCaTi based DLA structure
Group Velocity	$0.057c$
R/Q	$8.8k \Omega /m$
Shunt Impedance	$25.1 M \Omega /m$
Q	2865
Power ATTN	6.6dB/m
RF power needed to support 1MV/m gradient	27kW

Now, let's dig out some history

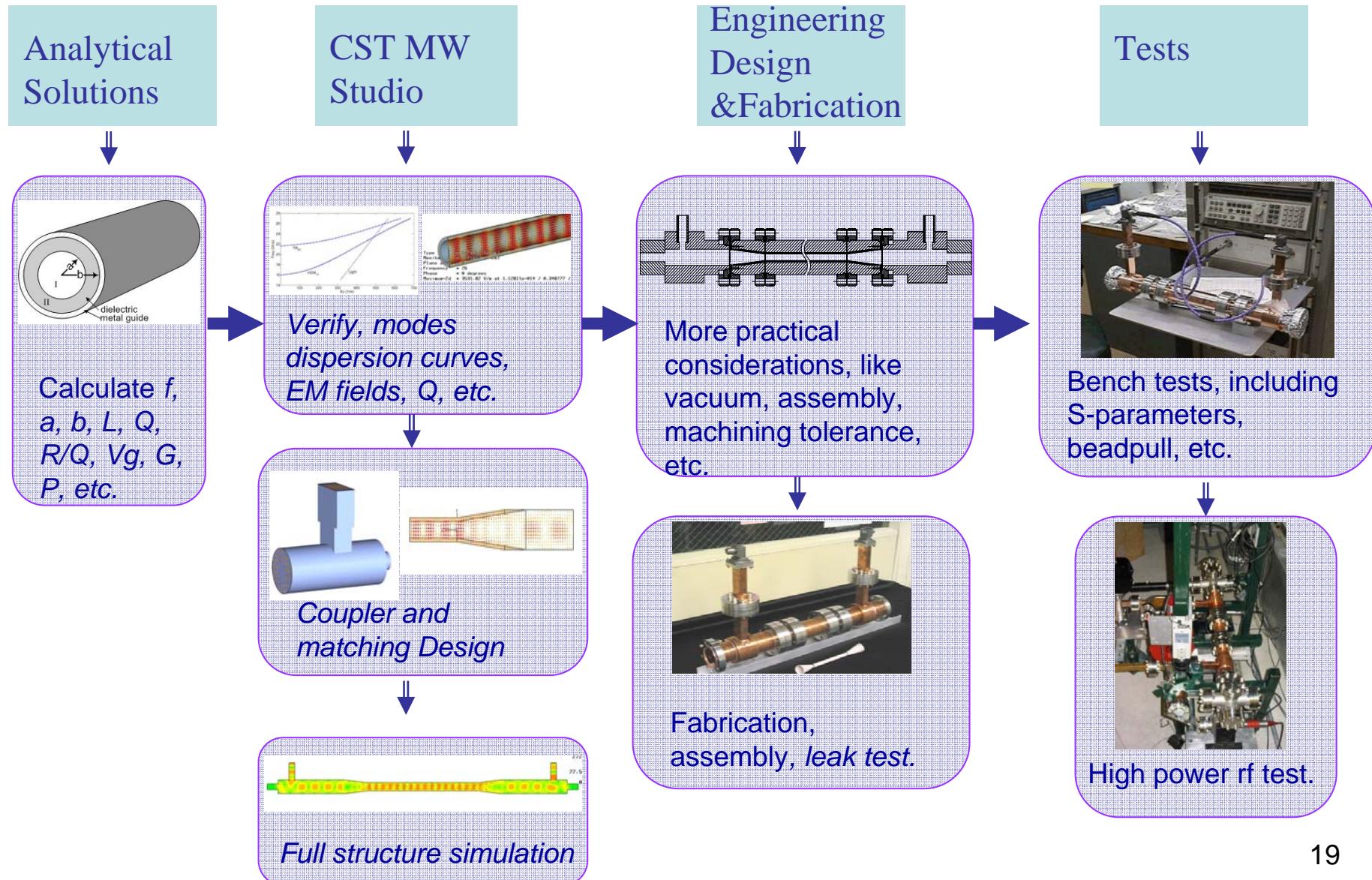
Experimental Studies of Dielectric Loaded Accelerator (1950s)

Major Research Group	Scientists	References	Research Scope
Atomic Energy Research Establishment (AERE), UK	R.B. R.-Shersby-Harvie, etc.	1. R.B. R.-Shersby-Harvie, <i>Nature</i> , 162 (1948) 890. 2. R.B. R.-Shersby-Harvie, etc., <i>Proc. I.E.E. B.</i> , 104 (1957) 273.	Constructed and Tested a 4MeV Traveling wave Dielectric Disk Loaded Accelerator. Beam Acceleration. Discovered Multipactor in DLA.
Queen Mary College, Uni. of London, UK	G.B. Walker, etc.	1. G.B.Walker and N.D.West, <i>Proc. I.E.E. C.</i> , 104 (1957) 381. 2. G.B.Walker and E.L.Lewis, <i>Nature</i> , 181 (1958) 38.	Constructed and Tested Dielectric Disk Loaded Wavguide Cavities. Tested Dielectric Breakdown.
IIT, USA	G.I. Cohn and G.T. Flesher	1. G.T.Flesher and G.I.Cohn, <i>A.I.E.E. C.</i> , 70 (1951) 887. 2. G.I.Cohn and G.T.Flesher, <i>IIT Report</i> , 2 (1952).	Constructed and Tested a Quartz Tube Based Dielectric Loaded Accelerator.

Part II: How to Make it?

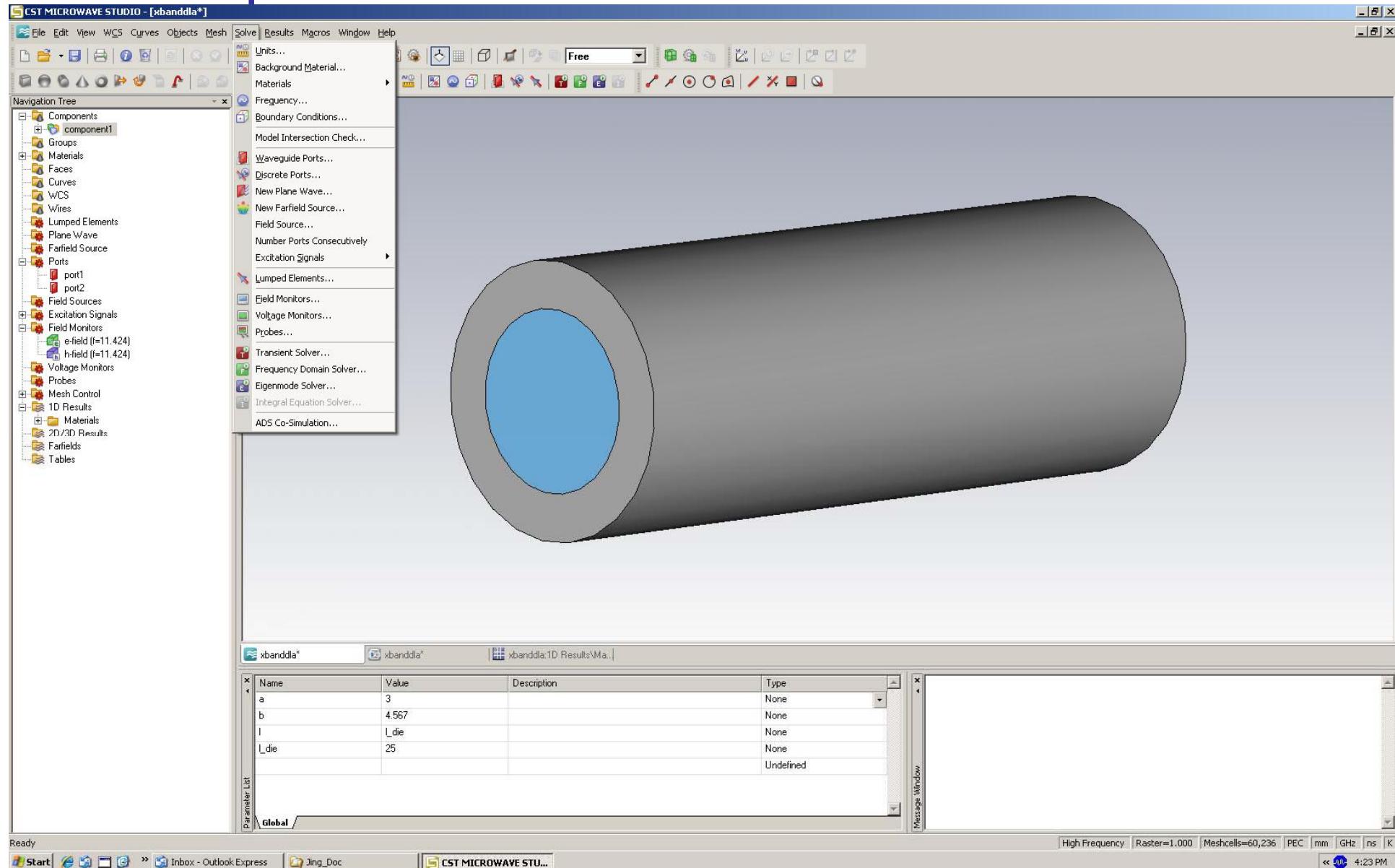
--- EM simulation, engineering
design, fabrication, etc.

How do we design a DLA structure using CST MWS?



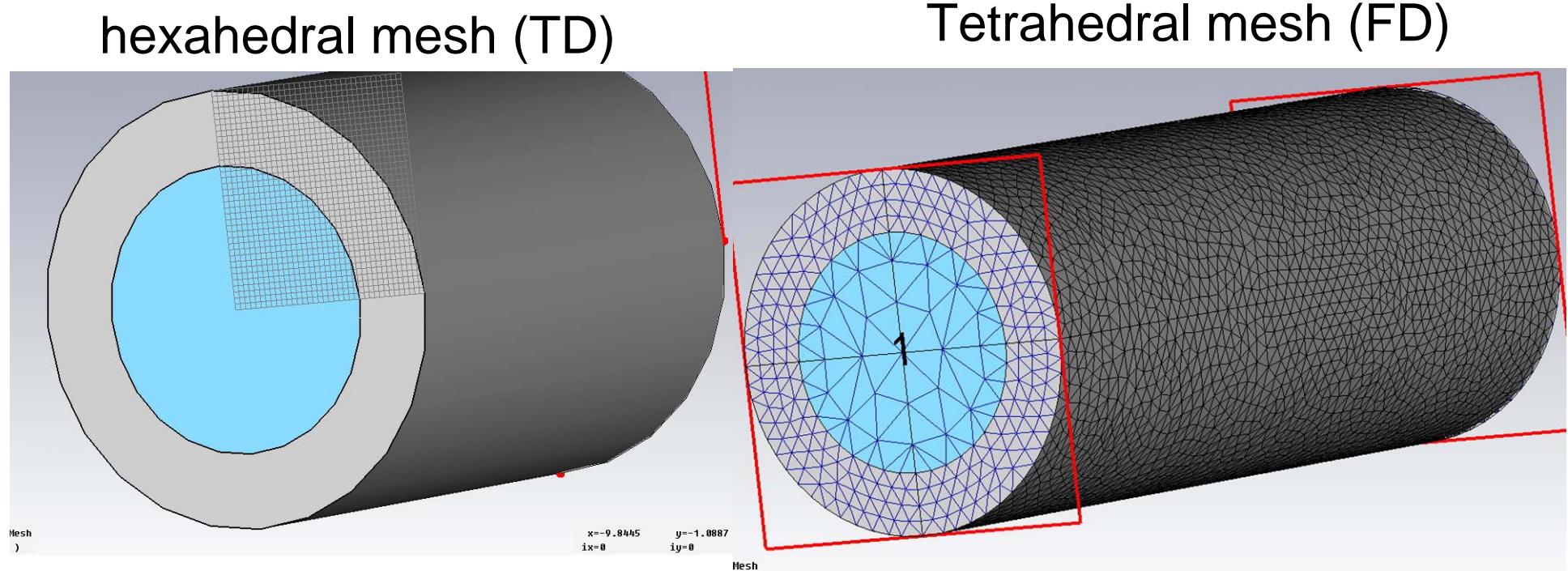
EM simulation of a DLA structure (I)

---set up a model



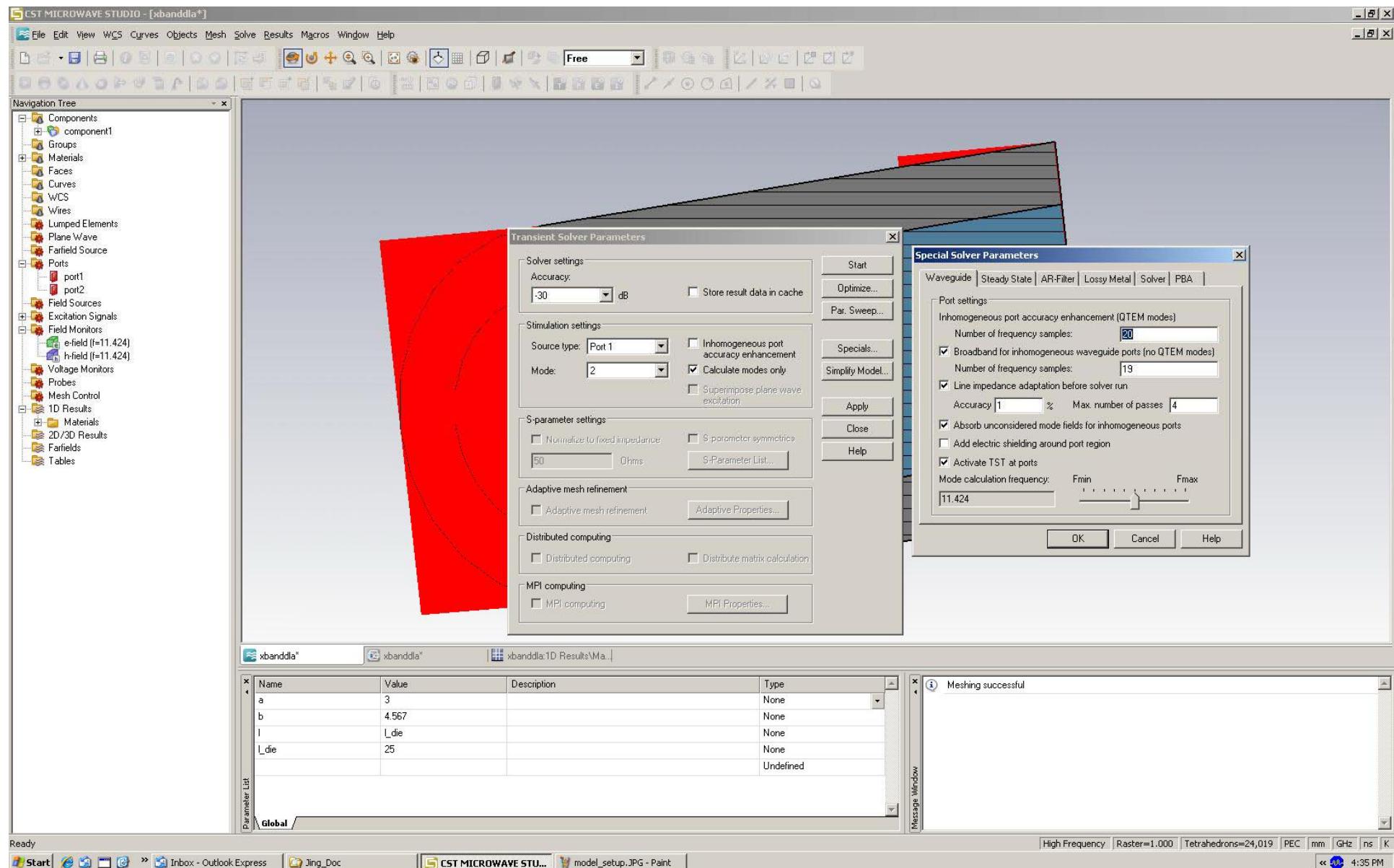
EM simulation of a DLA structure (II)

---mesh



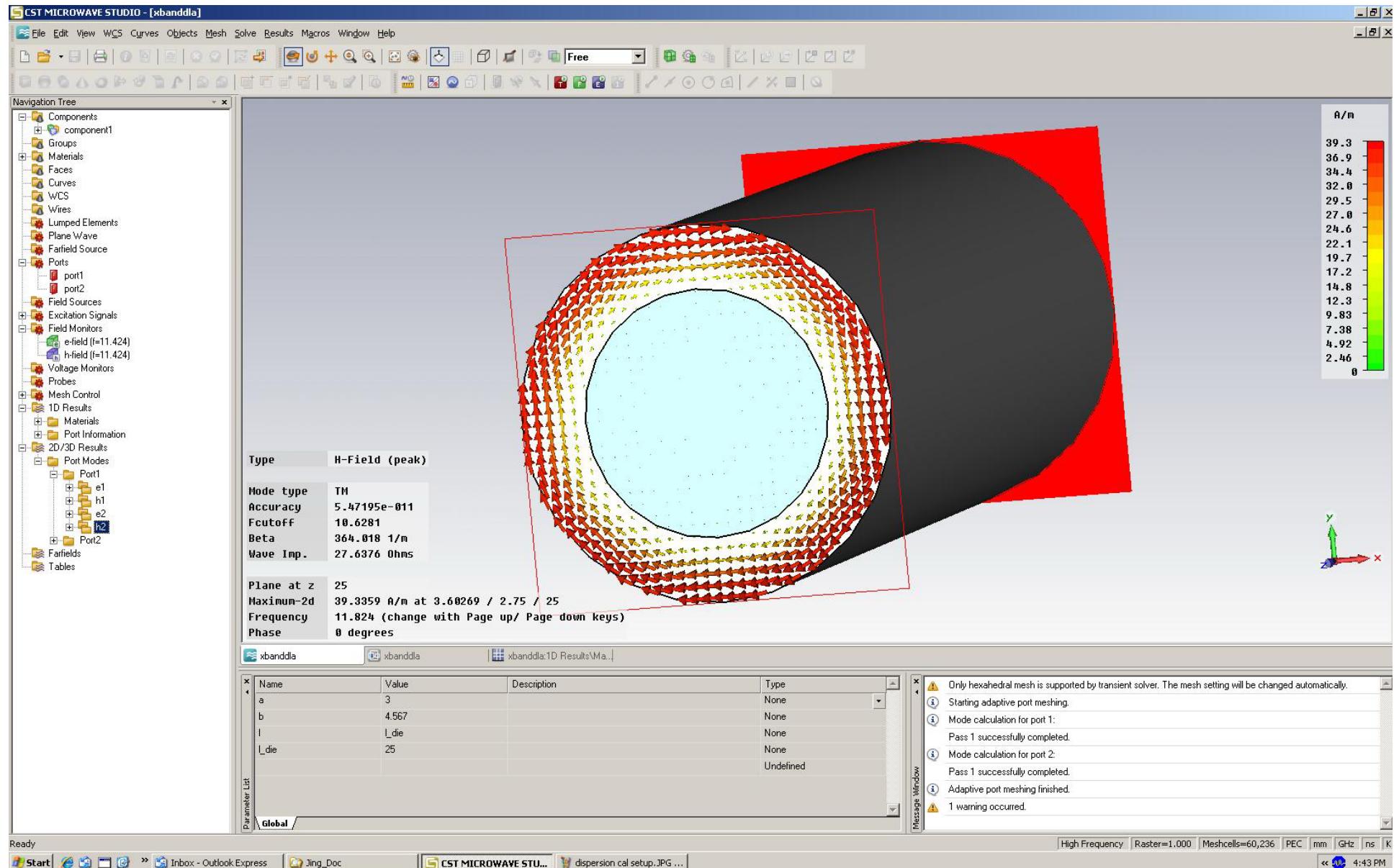
EM simulation of a DLA structure (III)

---set up the mode and dispersion cal

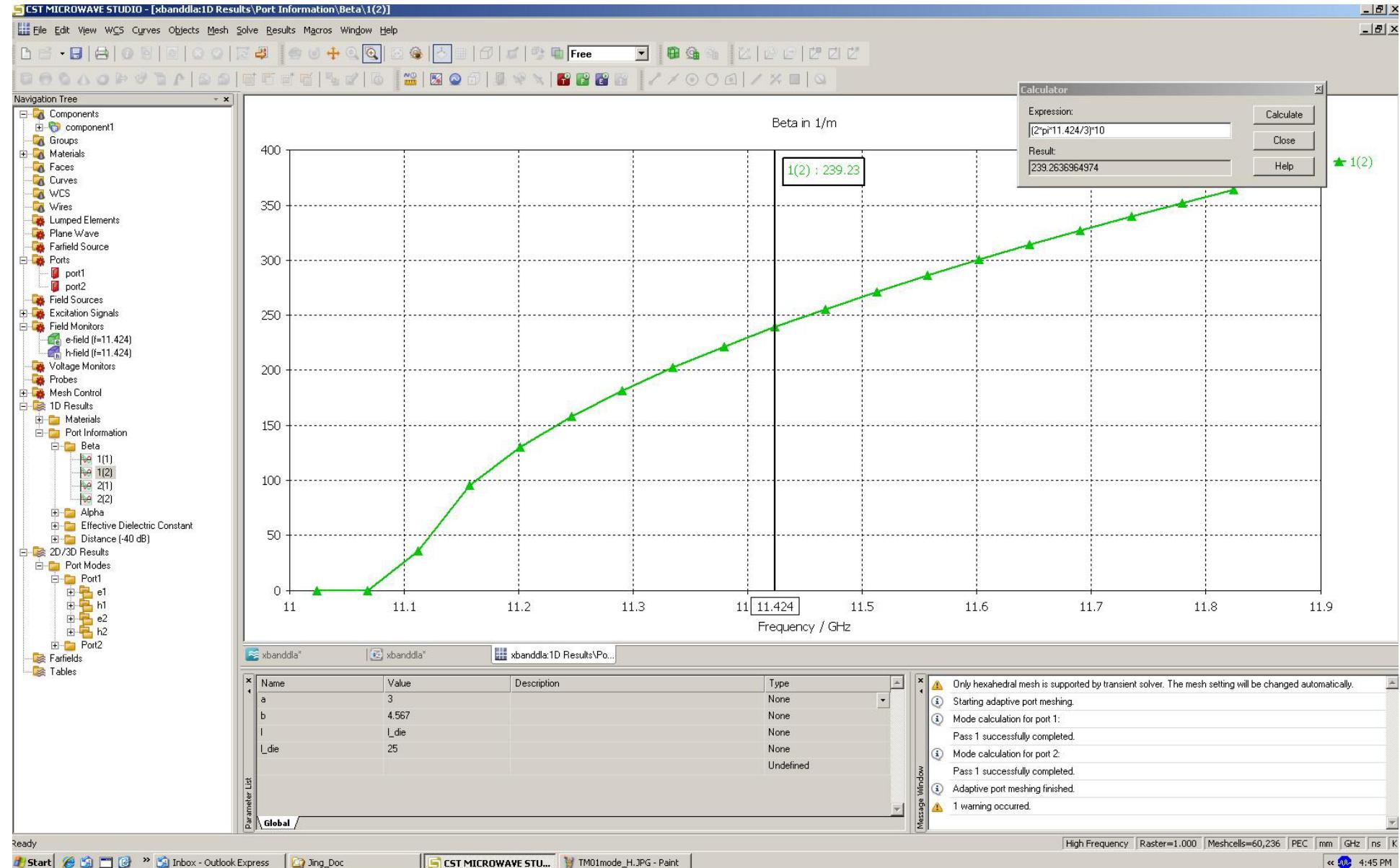


EM simulation of a DLA structure (III)

---mode

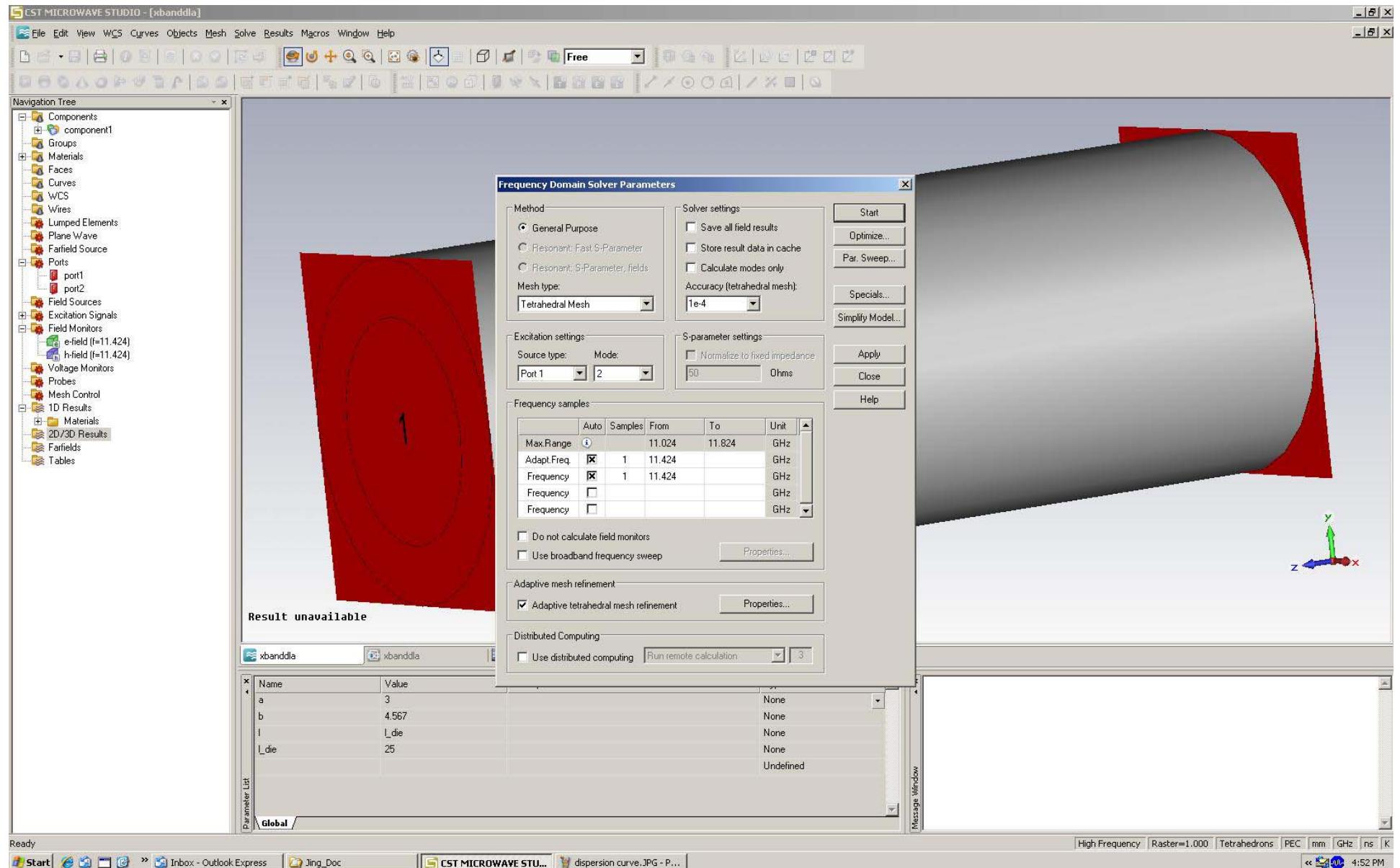


EM simulation of a DLA structure (III) ---dispersion



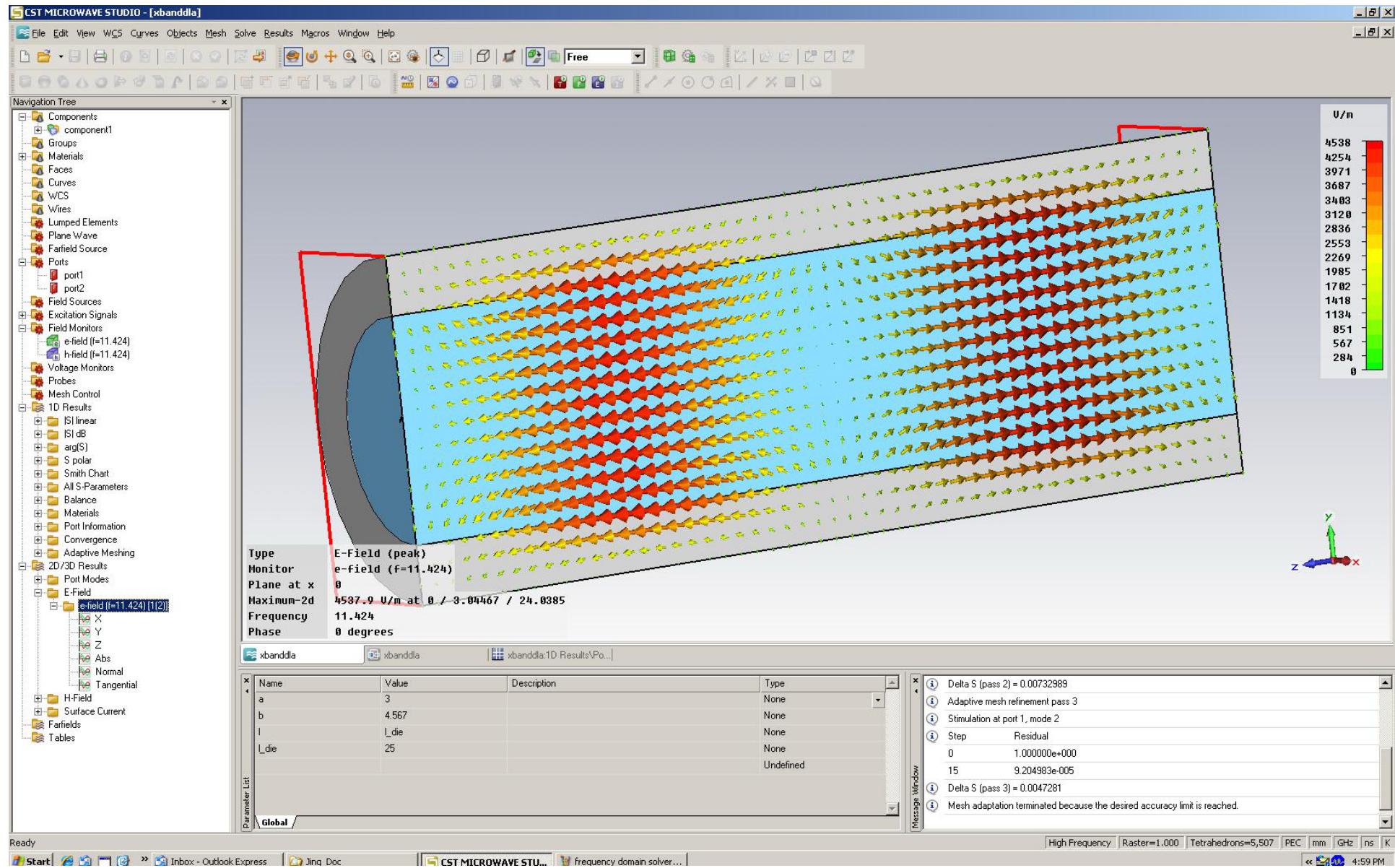
EM simulation of a DLA structure (IV)

---EM field simulation in FD



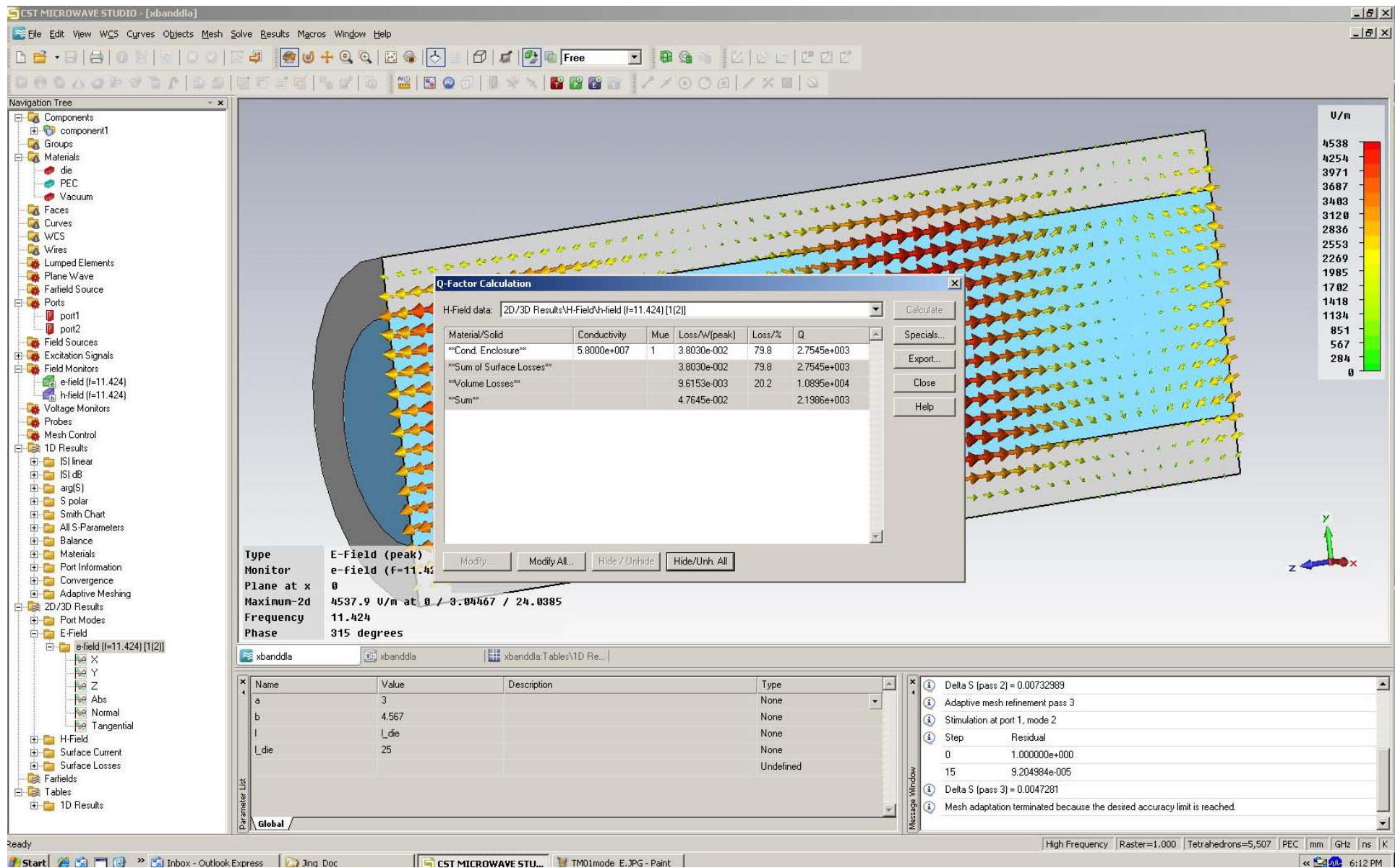
EM simulation of a DLA structure (IV)

---EM field simulation in FD



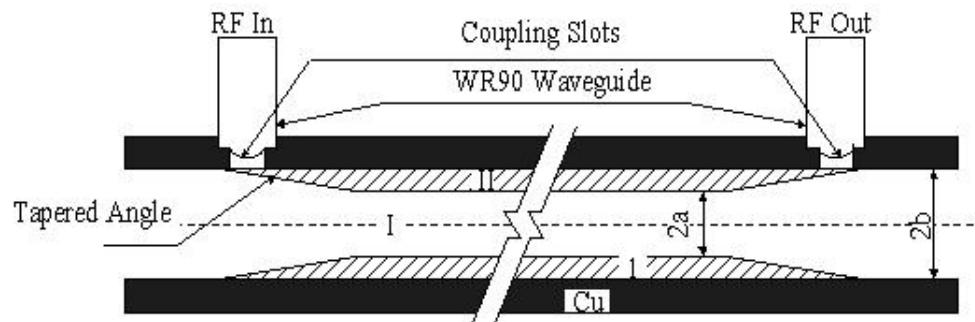
EM simulation of a DLA structure (IV)

---calculate acceleration parameters

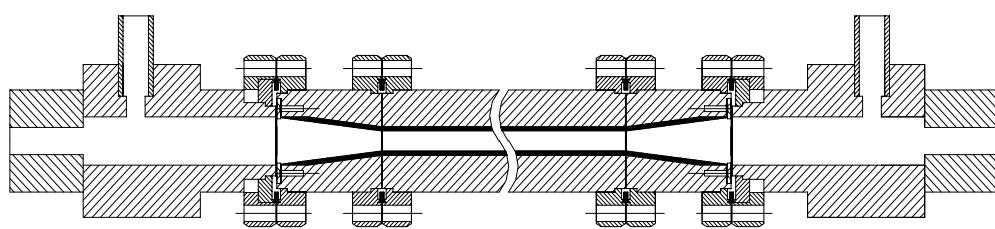


Now, we need figure out how to coupling the high power rf into the DLA structure.

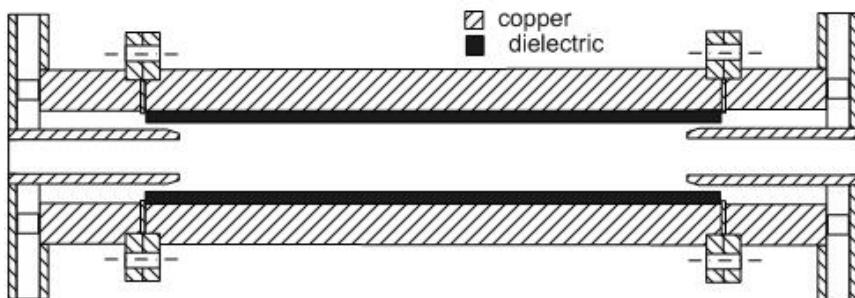
RF Coupling schemes--- TW (I)



Direct coupling

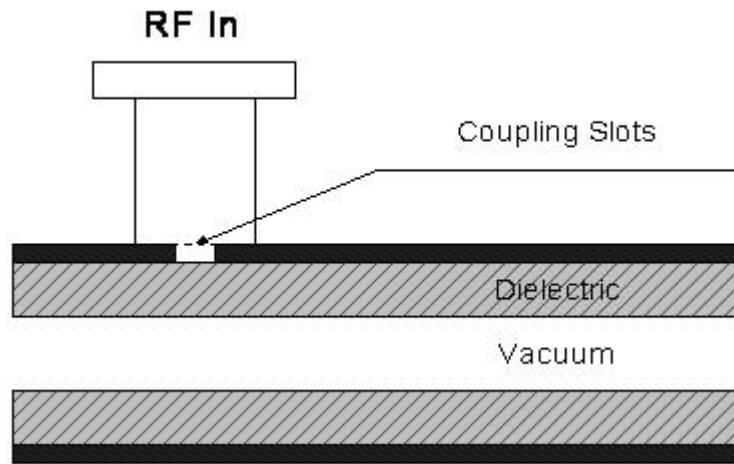


Mode launcher + impedance matching

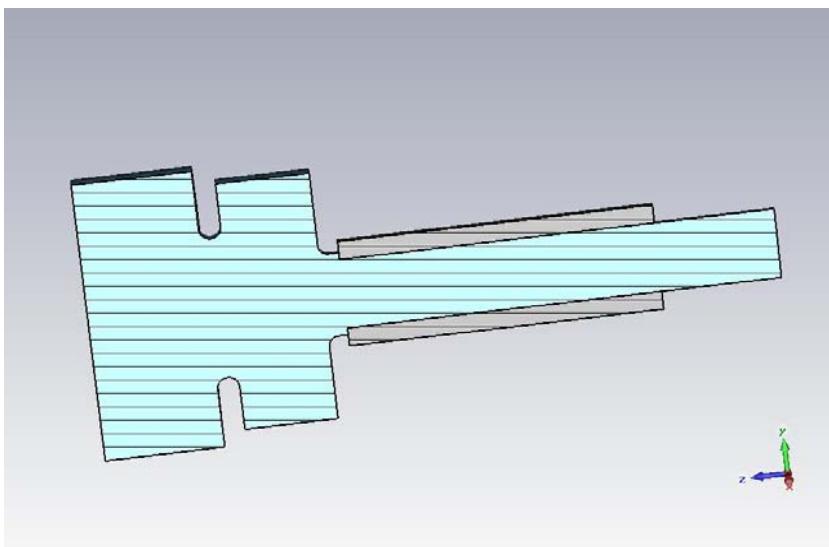


Coaxial type coupler

RF Coupling schemes--- SW



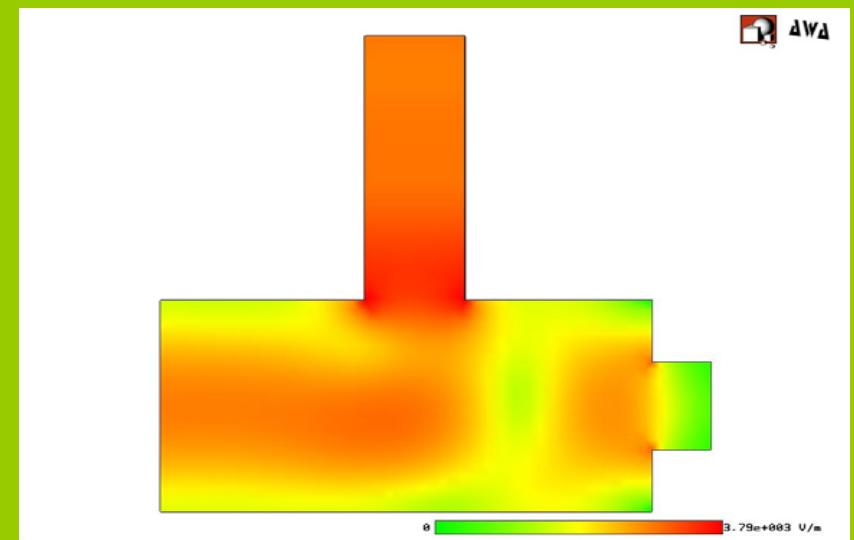
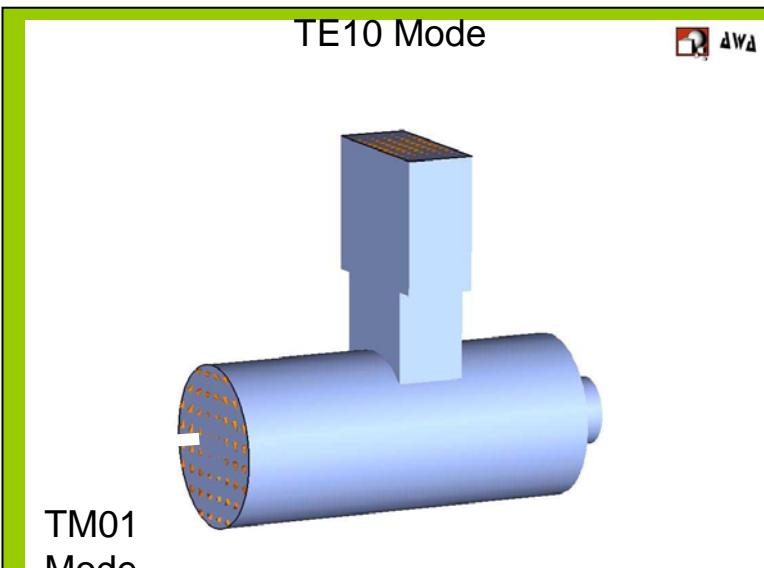
Side coupling



Axial coupling

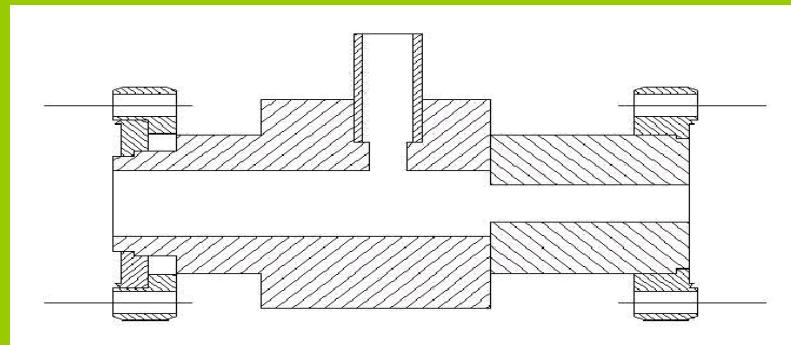
Example: modular structure design

Coupler Simulation



E-field in Coupler

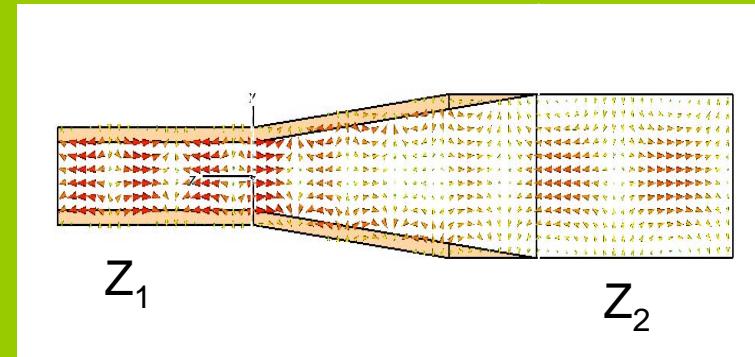
Peak electrical fields around the corners (blended at a radius of 2mm) of the coupling slot are to be less than 40 MV/m for 100 MW RF power, which is well below the copper surface breakdown threshold.



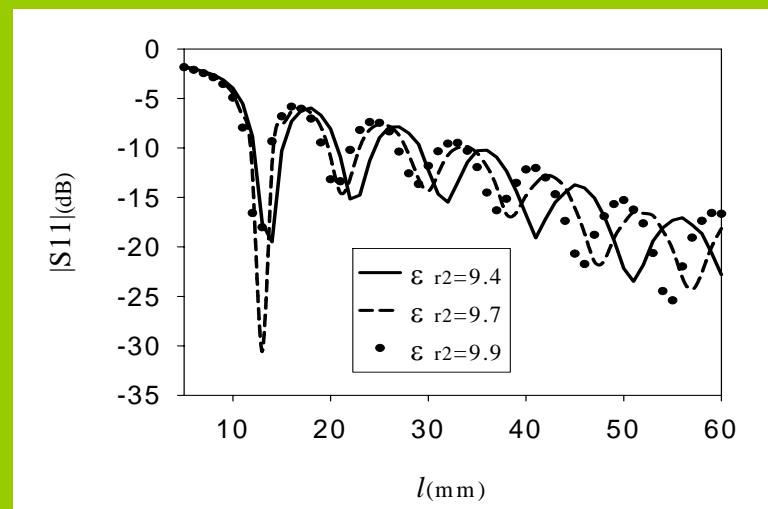
Mechanic Drawing

Matching Section Simulation and Making

Purpose of the tapered matching section is to match the wave impedance between the dielectric loaded circular waveguide (dielectric loaded accelerator section) and the regular circular waveguide where the RF coupling structure is implemented, thus achieve high transmissions.



E-field pattern for taper section

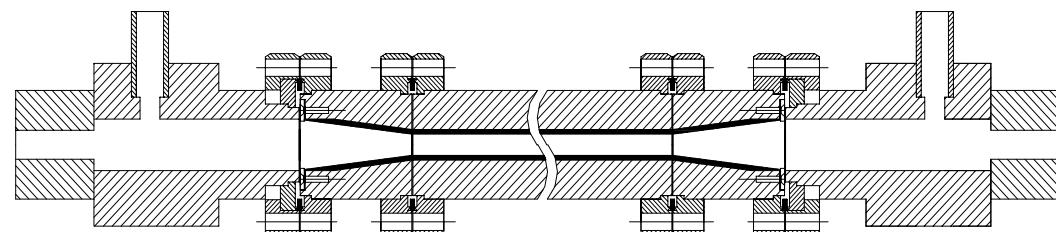
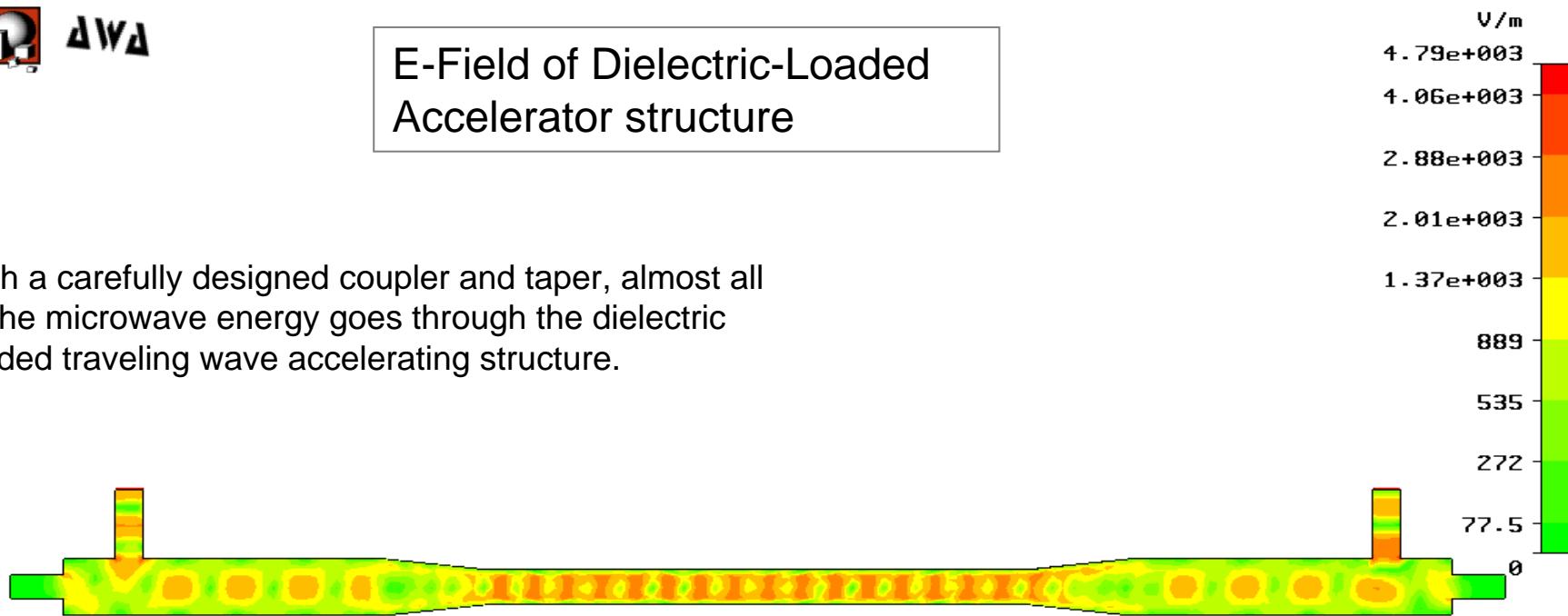


Length vs. Performance (S_{11})



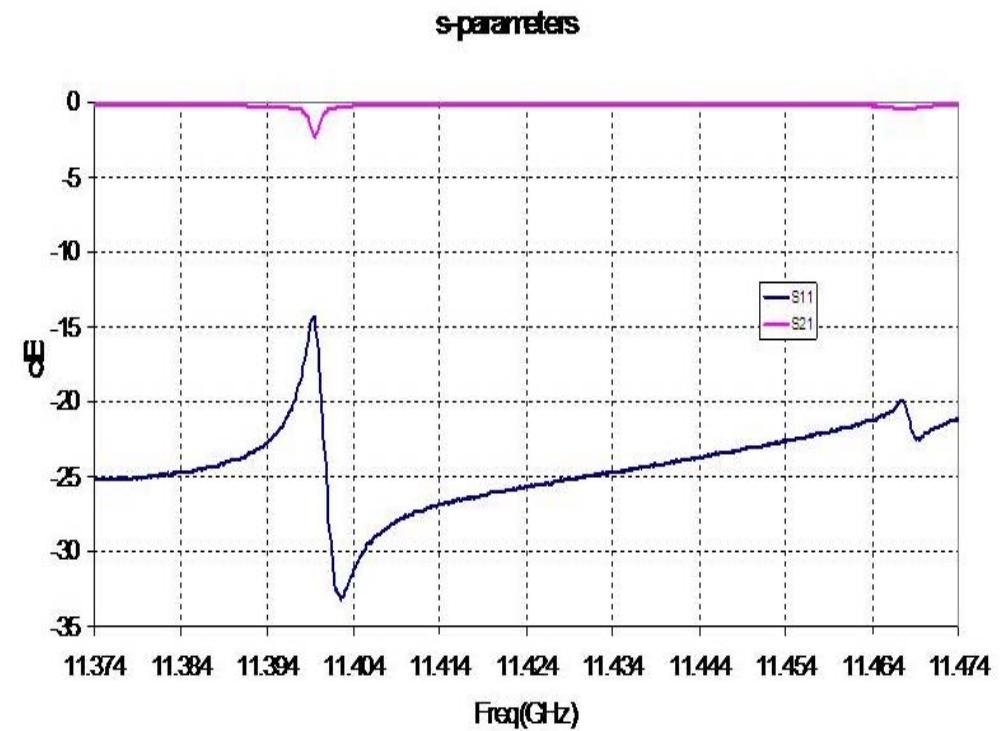
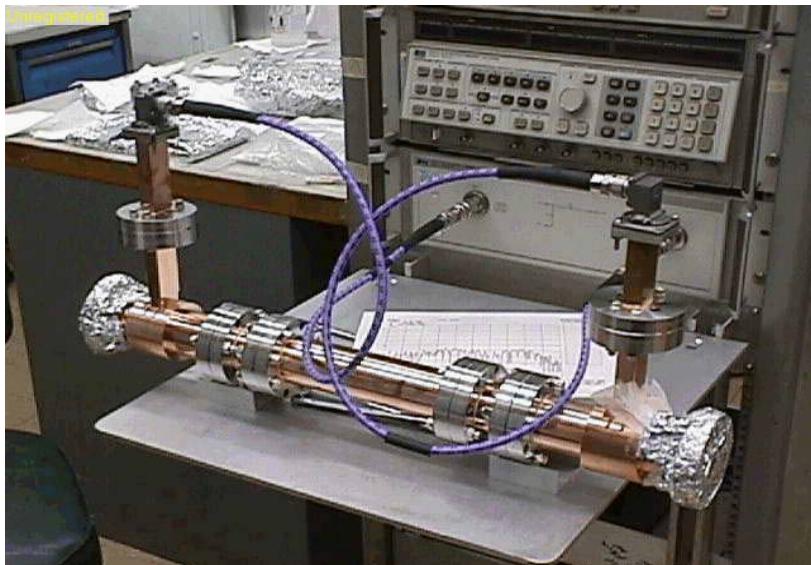
E-Field of Dielectric-Loaded Accelerator structure

With a carefully designed coupler and taper, almost all of the microwave energy goes through the dielectric loaded traveling wave accelerating structure.

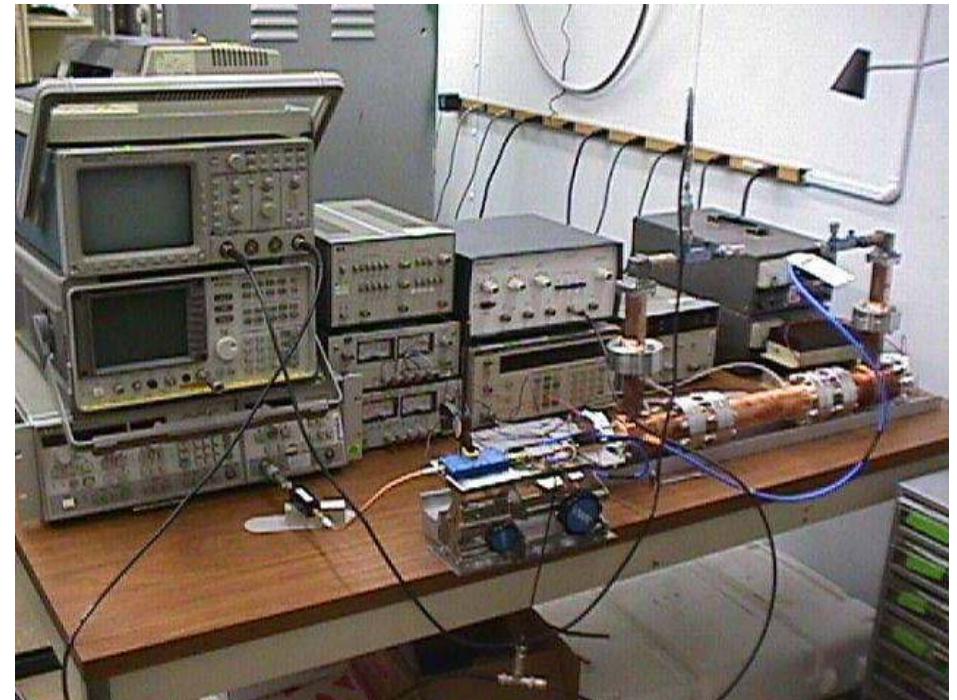


With properly selected dielectric constant and loading geometry, the wave in the dielectric loaded accelerating structure will travel at the speed of light and its pattern is good for accelerating the particles at the given frequency, here, 11.424GHz

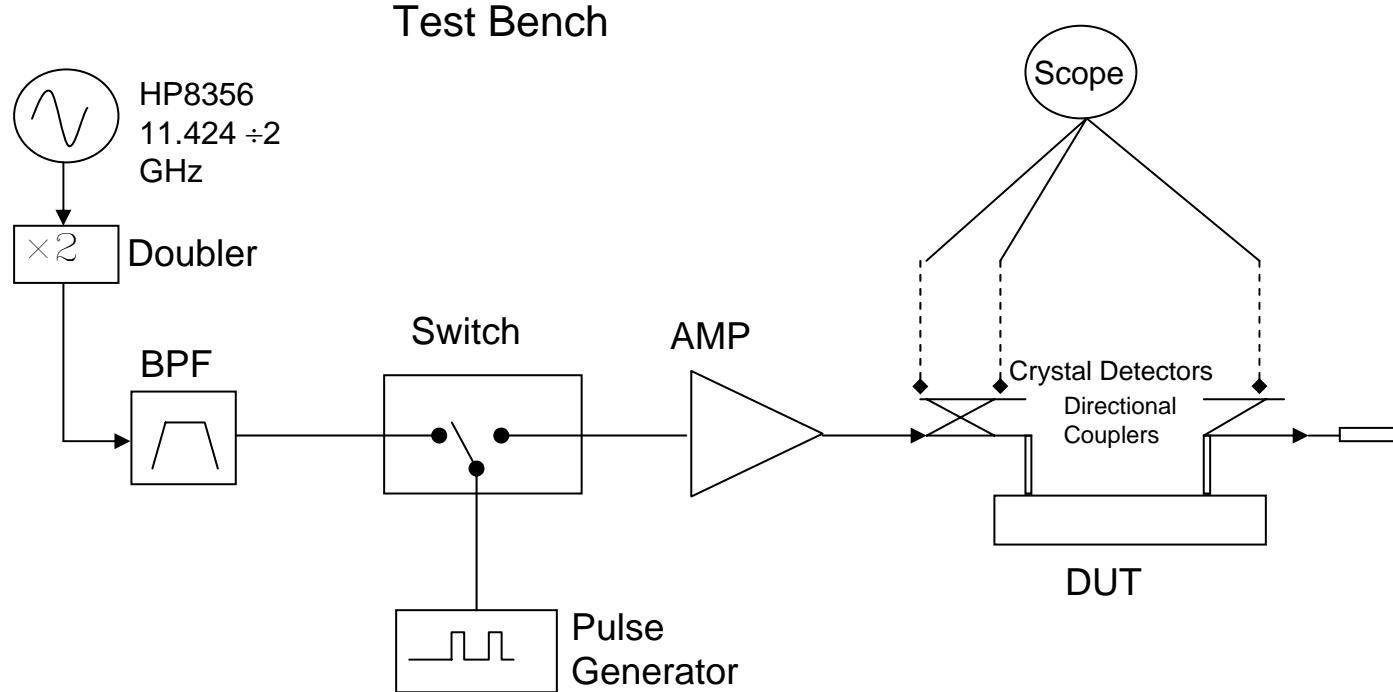
Bench Test: S-parameter measurement.



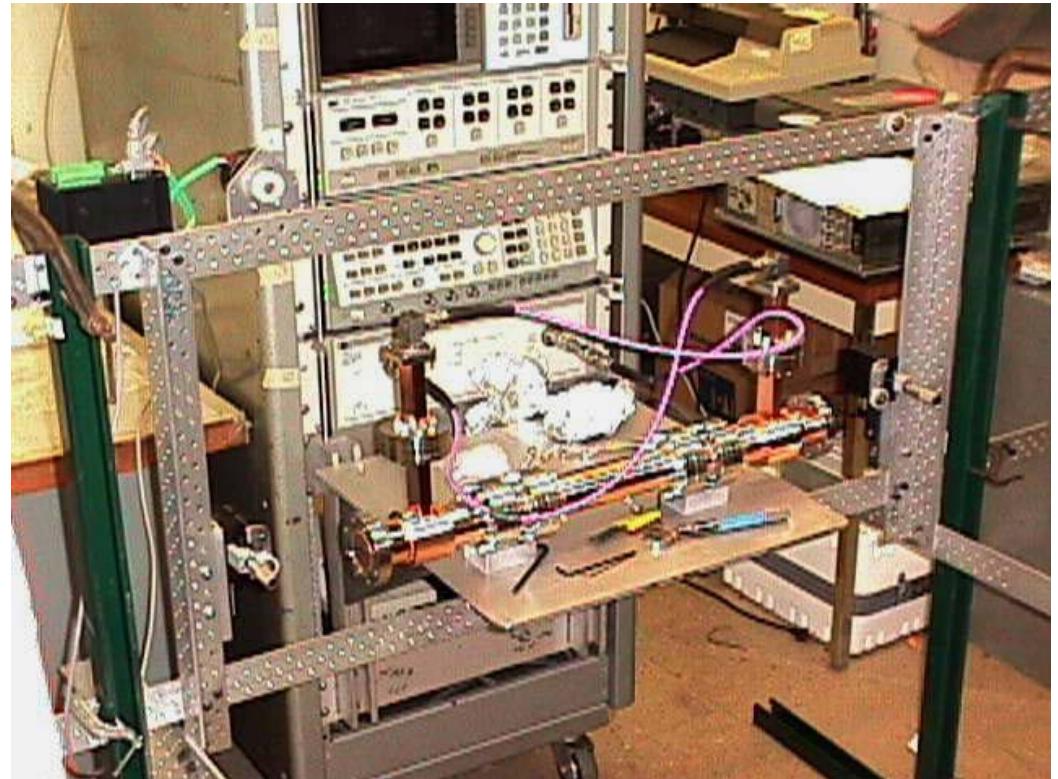
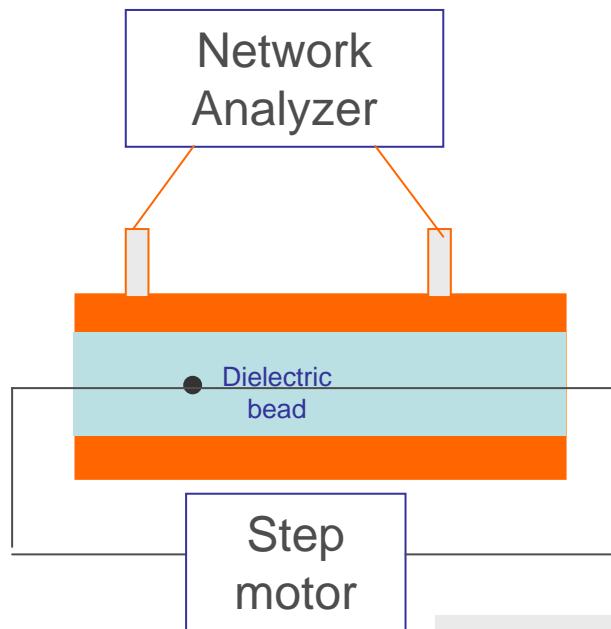
Bench Test: Low power pulsed rf bench test on X-band DLA structure



11.424GHz Time Response
Test Bench



Bench Test: Beadpull
experiment to obtain the profile
of accelerating field.



Standing Wave Case

$$\frac{\Delta\omega}{\omega} = -\frac{\epsilon\alpha_e}{4U}|E|^2$$

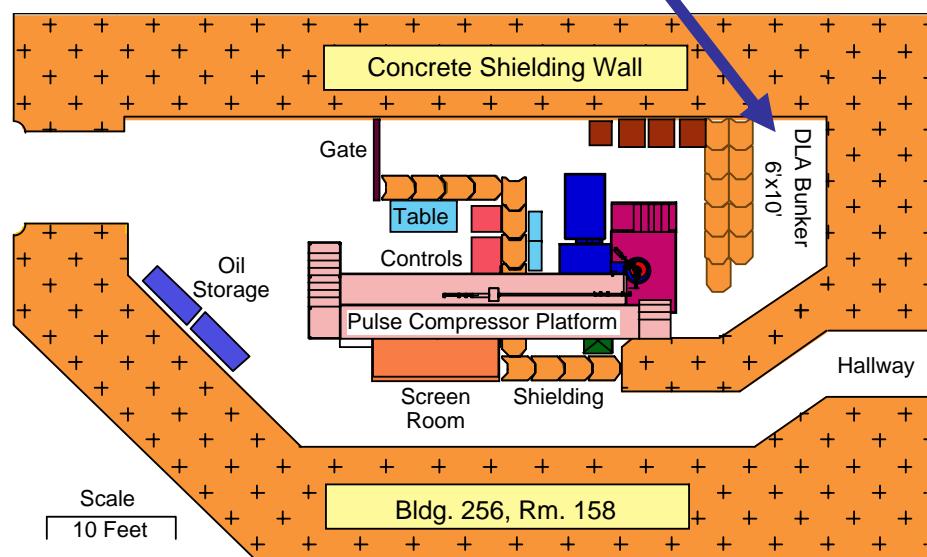
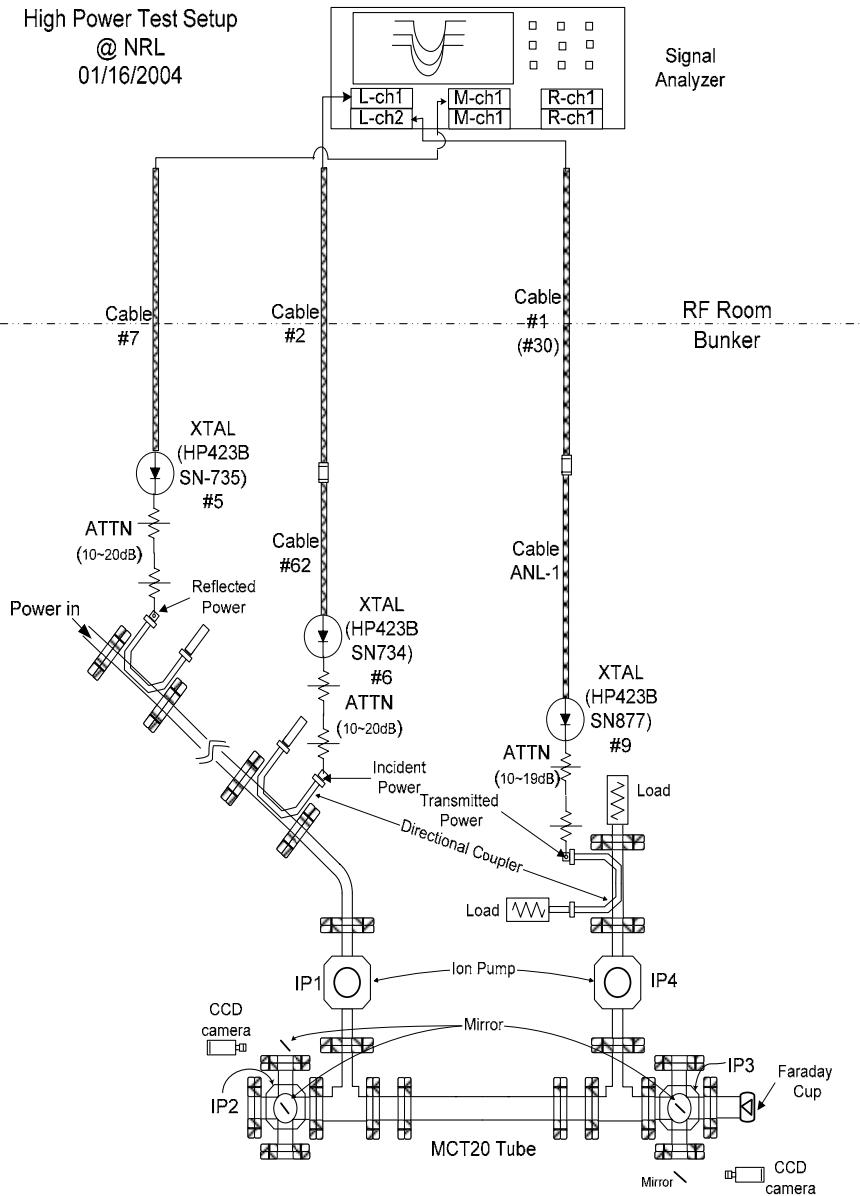
Traveling Wave Case

$$\Delta S_{11} = -\frac{j\omega}{2P_i}(\epsilon\alpha_e|E|^2 - \mu\alpha_m|H|^2)e^{j2\phi}$$

For dielectric bead $\alpha_e=4\pi r^3$, $\alpha_m=0$

High Power rf Test

High Power Test Setup
@ NRL
01/16/2004

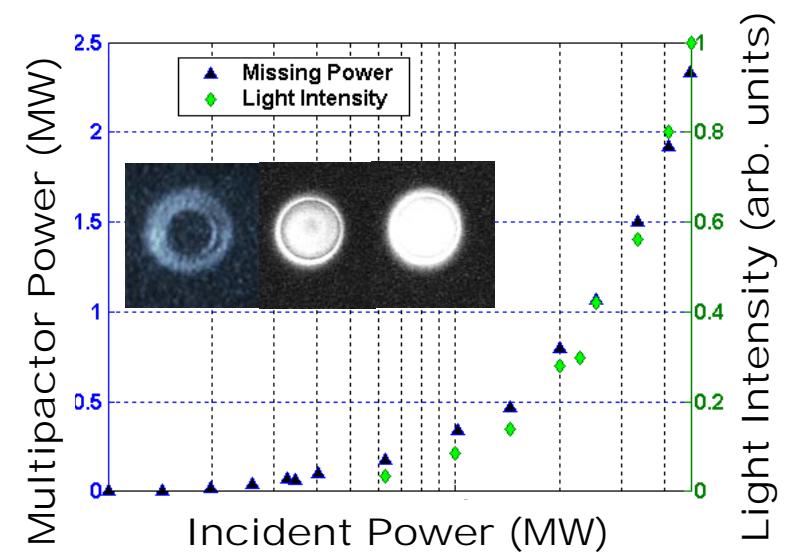
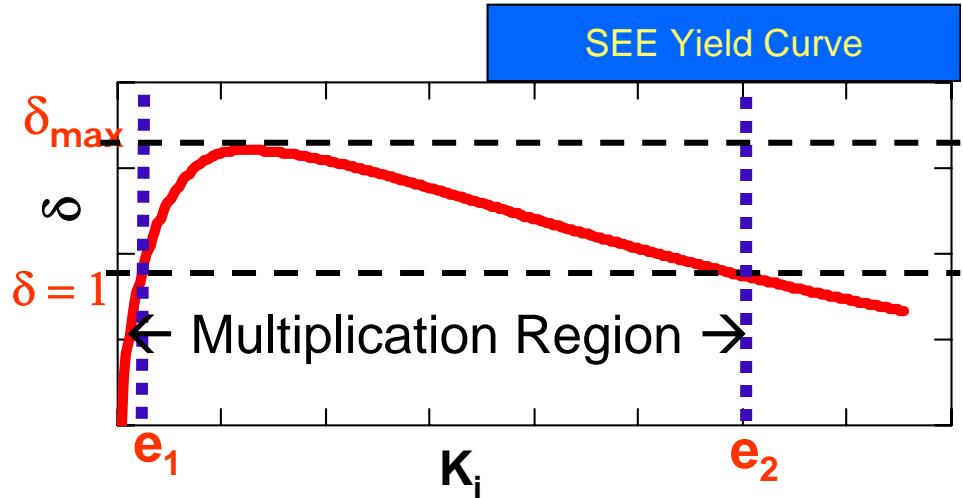
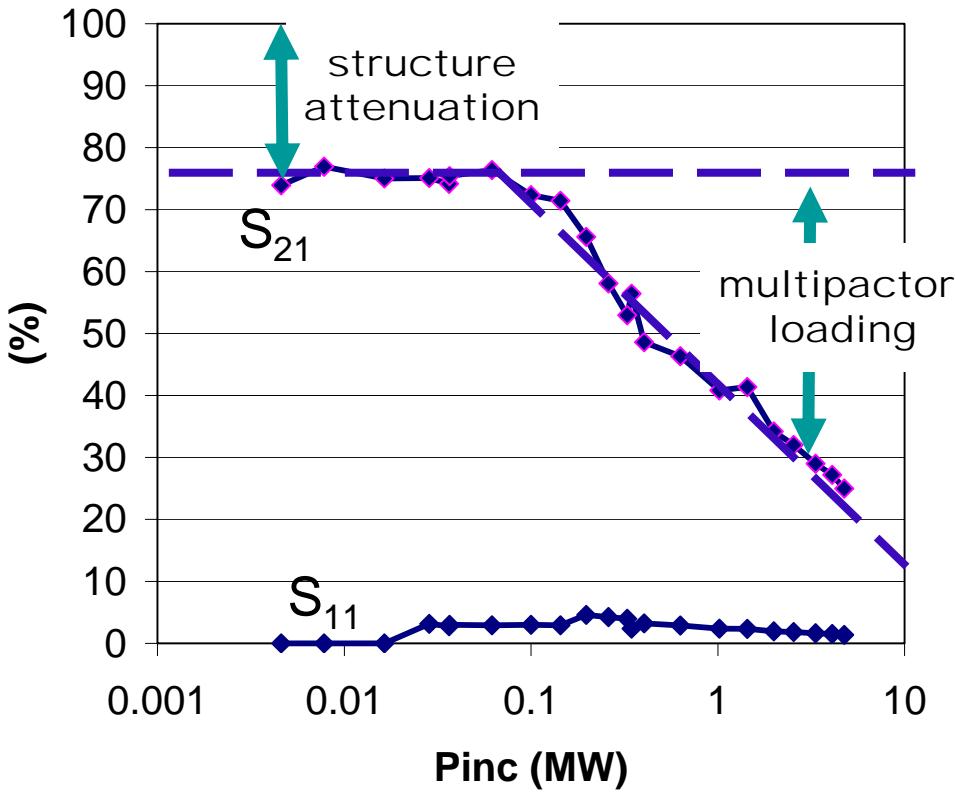
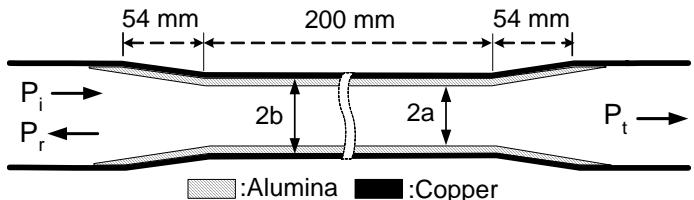


Part III: Does It Work Well?

_____ challenges found out of
the experiments

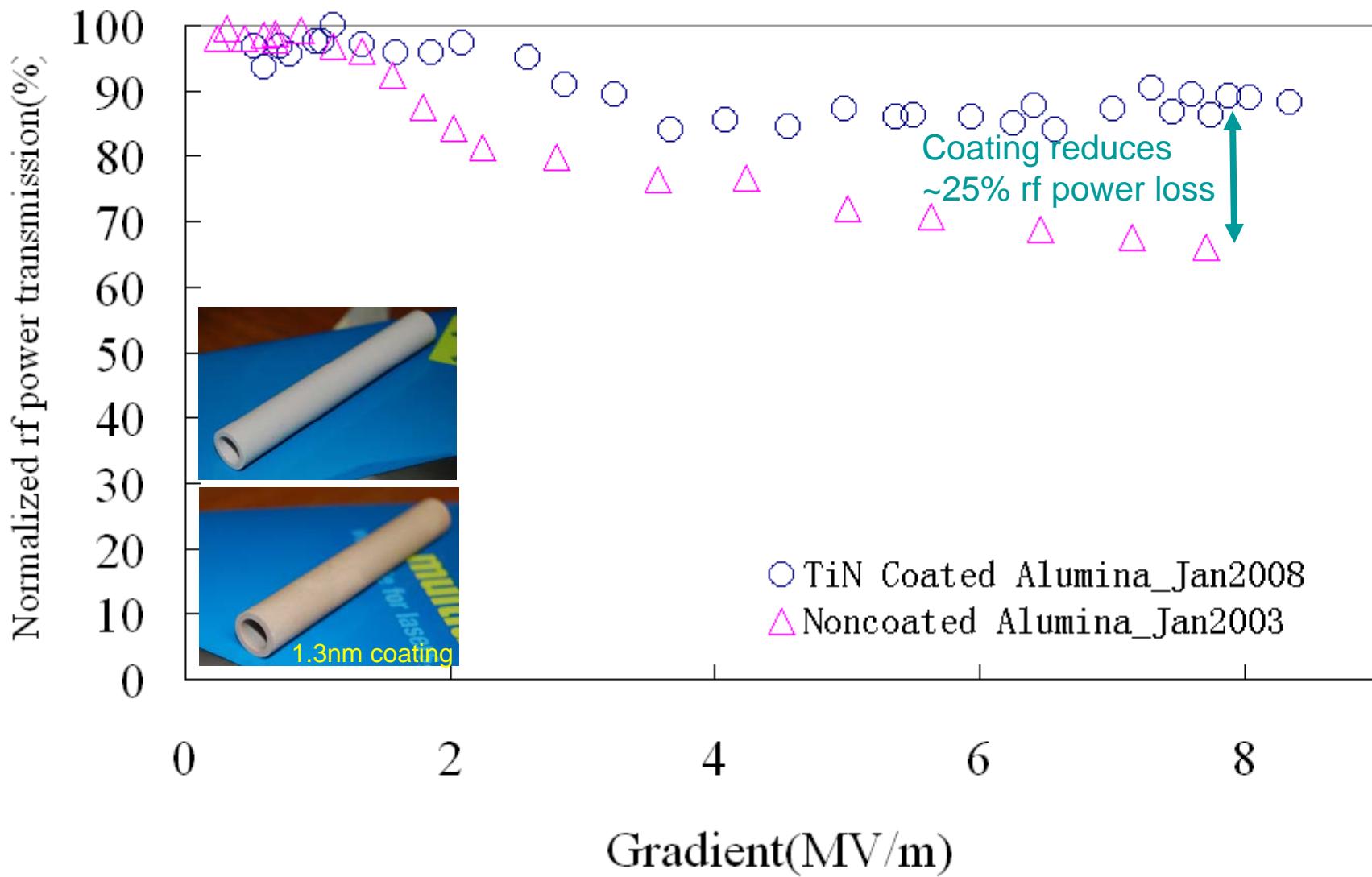
Multipactor

[ref5]. J.G. Power, et al. Phy. Rev. Lett. 92, 16, 2004, pp. 164801 (2004).



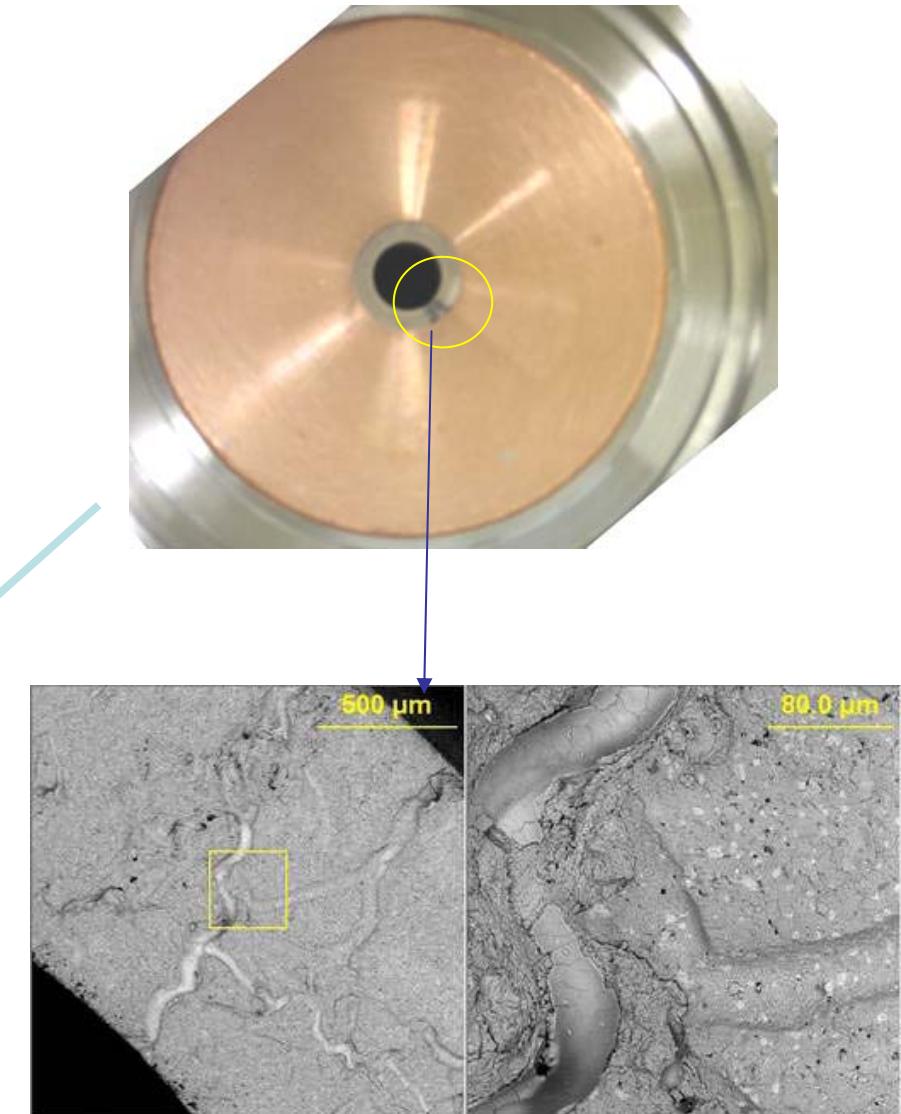
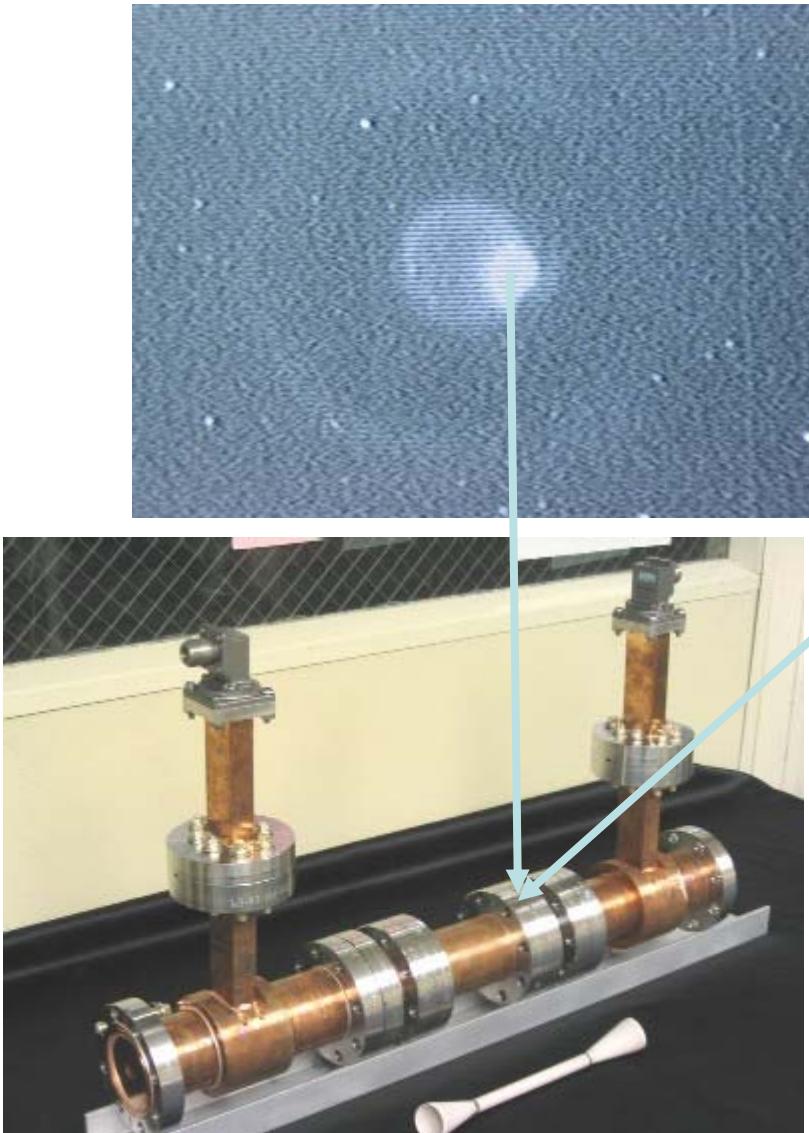
Multipactor suppression

Coating/ better material/ geometrical factor, like grooves

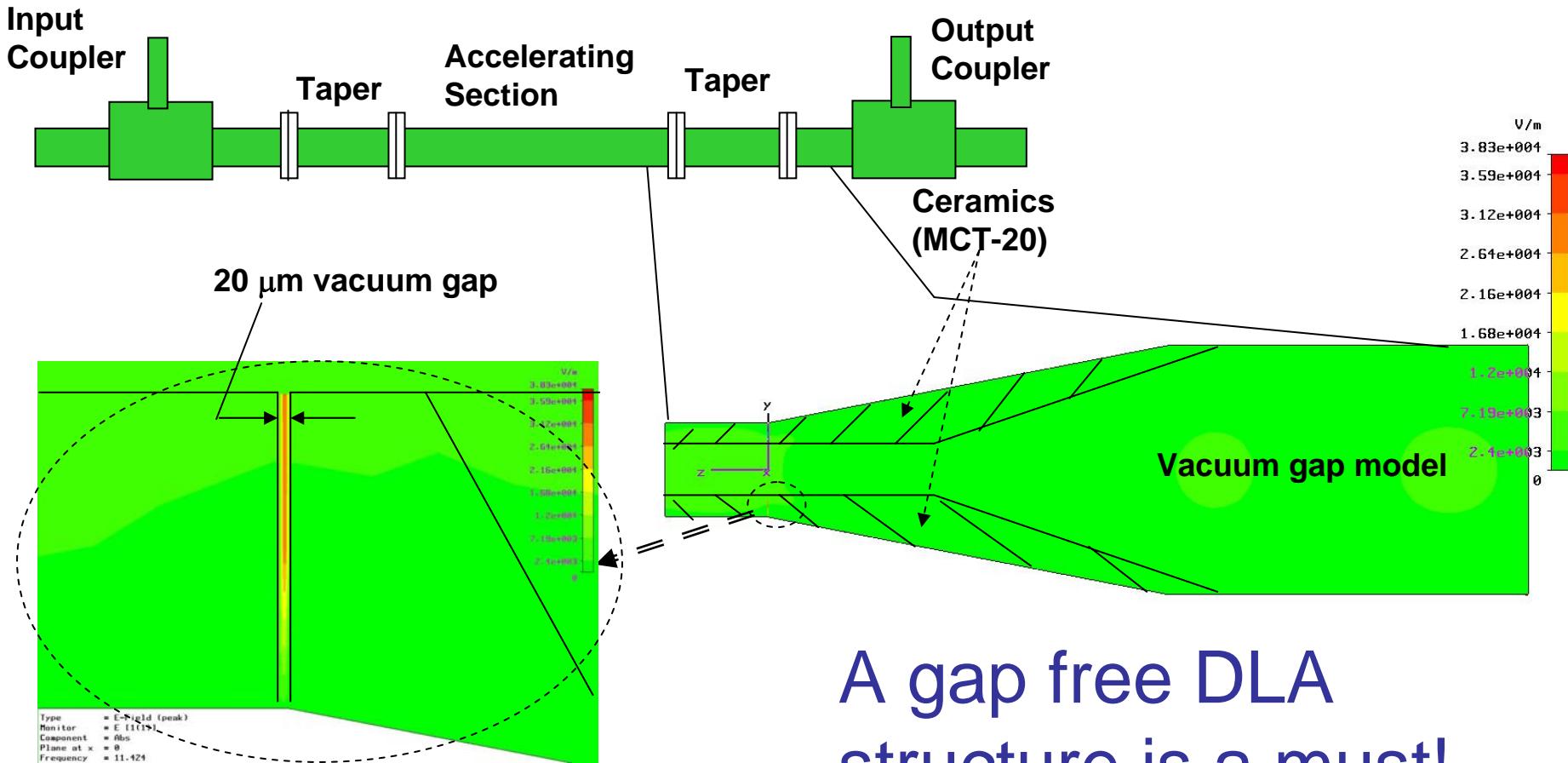


Dielectric BD @ the joint

[ref6]. C. Jing, et al. IEEE, Trans. PS,
vol.33 No.4, Aug. 2005, pp.1155-1160.



Simulation on E-field enhancement from introduced air gap by Microwave Studio®

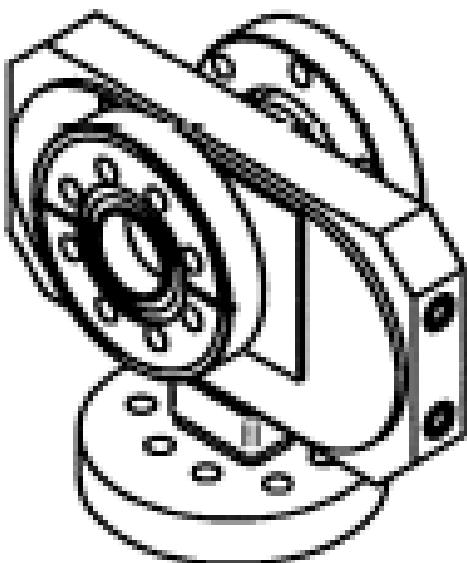


A gap free DLA
structure is a must!

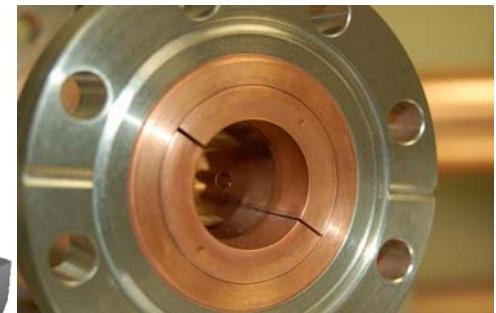
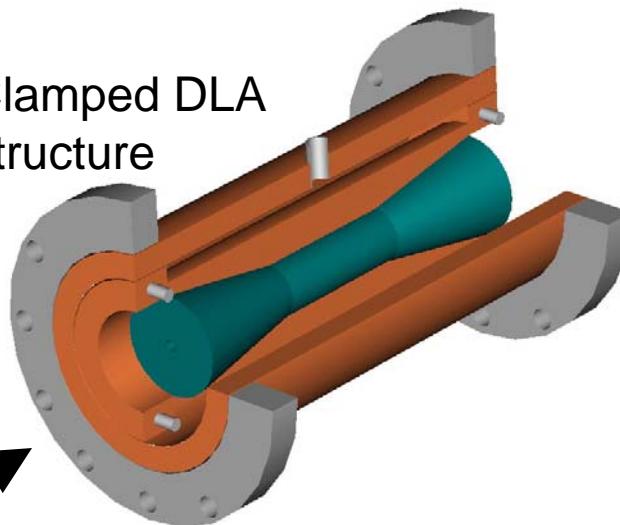
Compared to normal case (no air gap), at that position, the electrical field at the edge of the gap increased >20 times.

Gap Free DLA structures

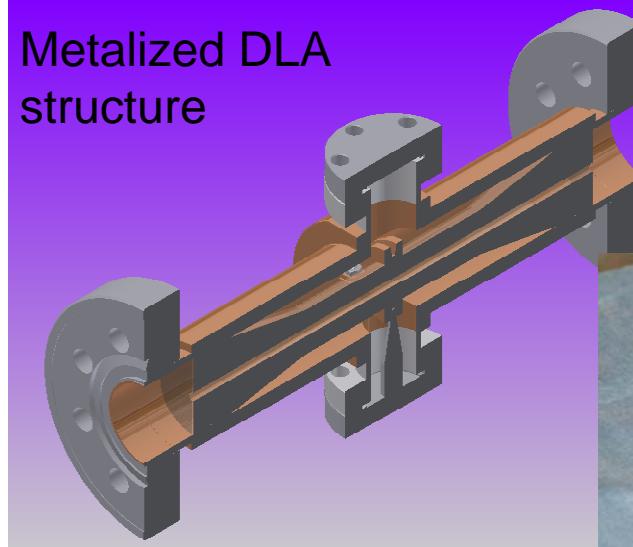
Well tested mode launcher



Clamped DLA structure



Metalized DLA structure



Part IV: More advanced topics

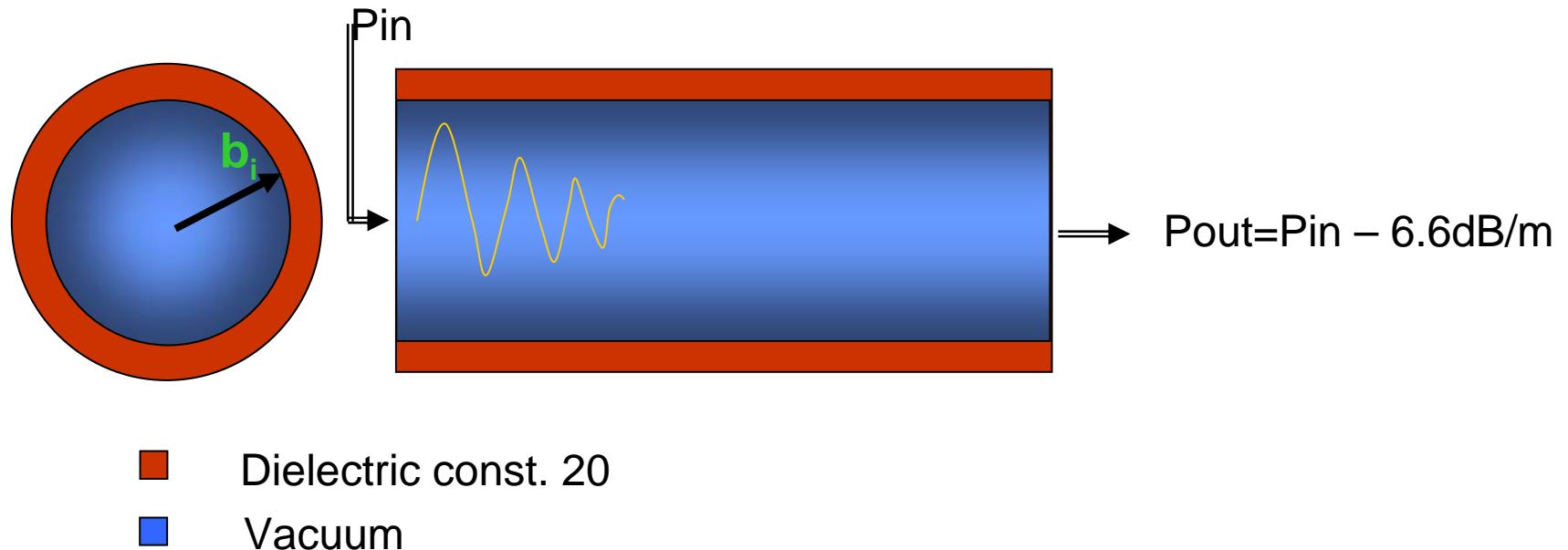
multilayered DLA,
transverse mode damping,
frequency tuning, hybrid DLA,
etc.

1. Multilayer Dielectric-Loaded Accelerating Structure

[ref7]. C. Jing, et al. Nuclear Instr. Metho. in Phy. Research A, Vol.539, Mar. 2005, pp.445-454.

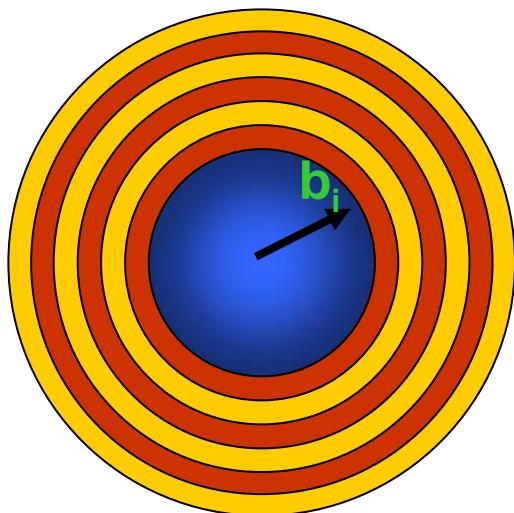
Motivation

- Well-developed single layer dielectric-loaded accelerating (DLA) structure has trouble in large RF power attenuation along the structure.



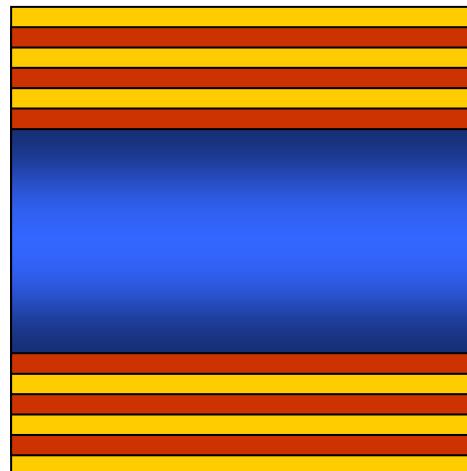
Benefit from theory of Bragg fiber

Field is confined by radial periodical ceramic layers

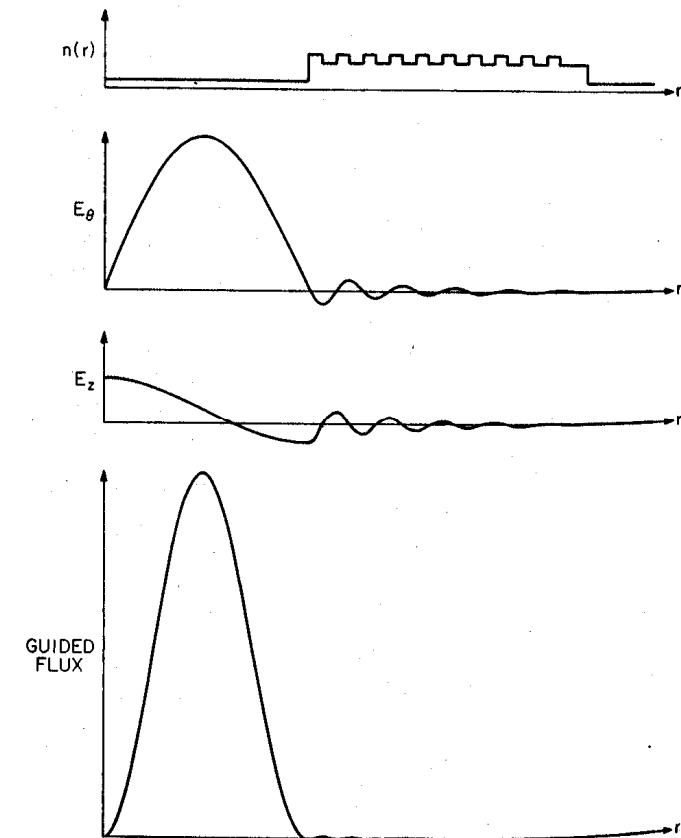


3-D

- Ceramic with high permittivity
- Ceramic with low permittivity
- Air



2-D

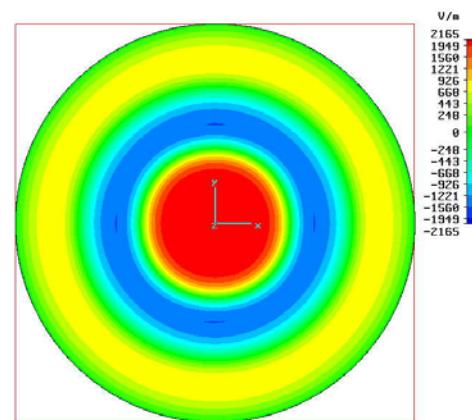
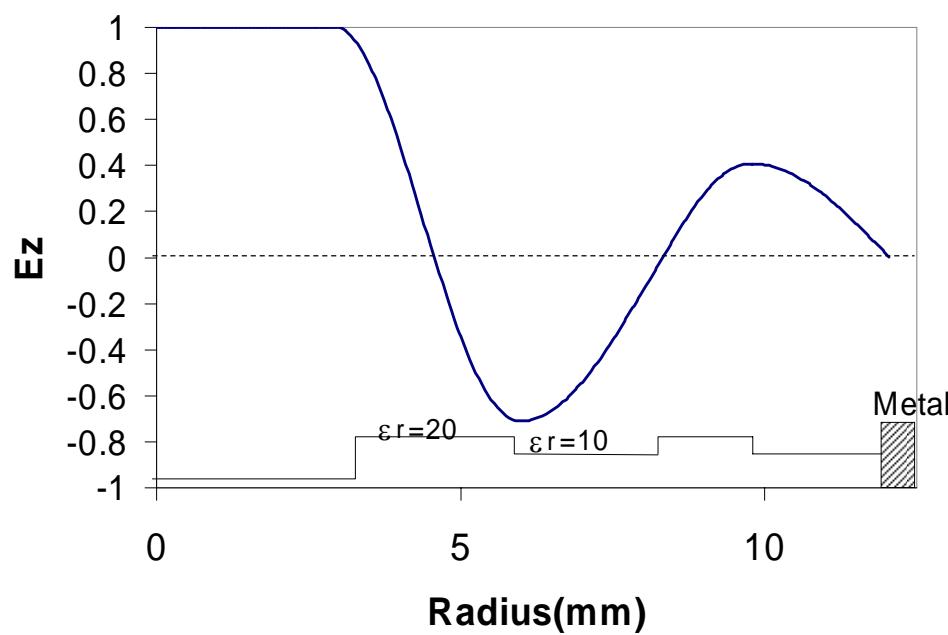
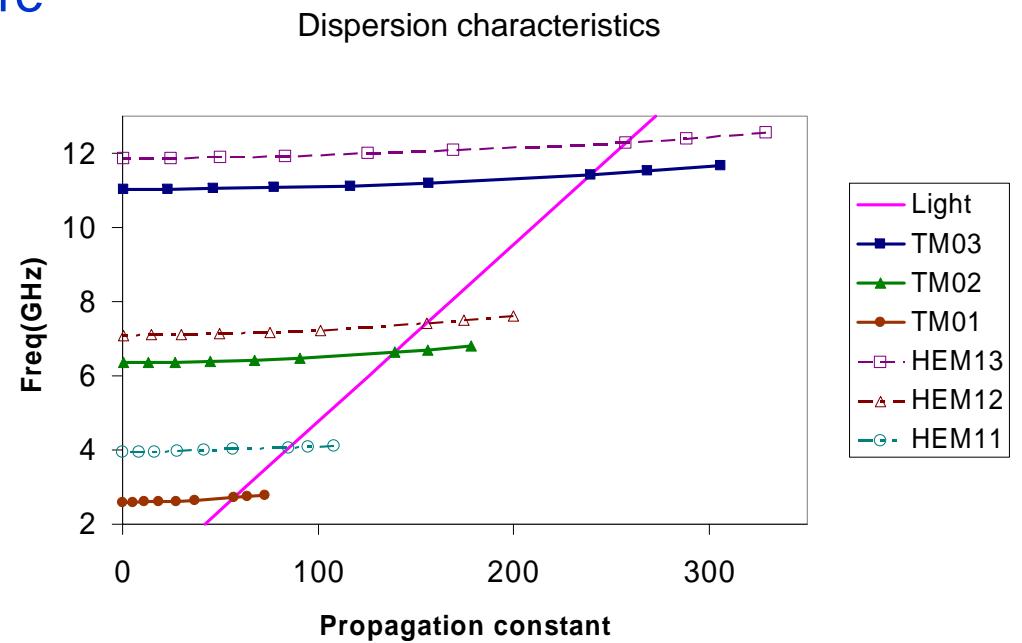
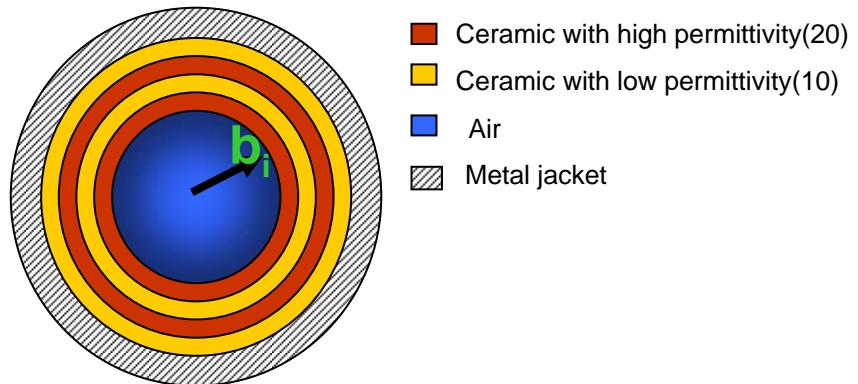


Typical Field distribution and guided flux in a bragg fiber

Courtesy of P. Yeh J. Opt. Soc. Am Vol.68 1978

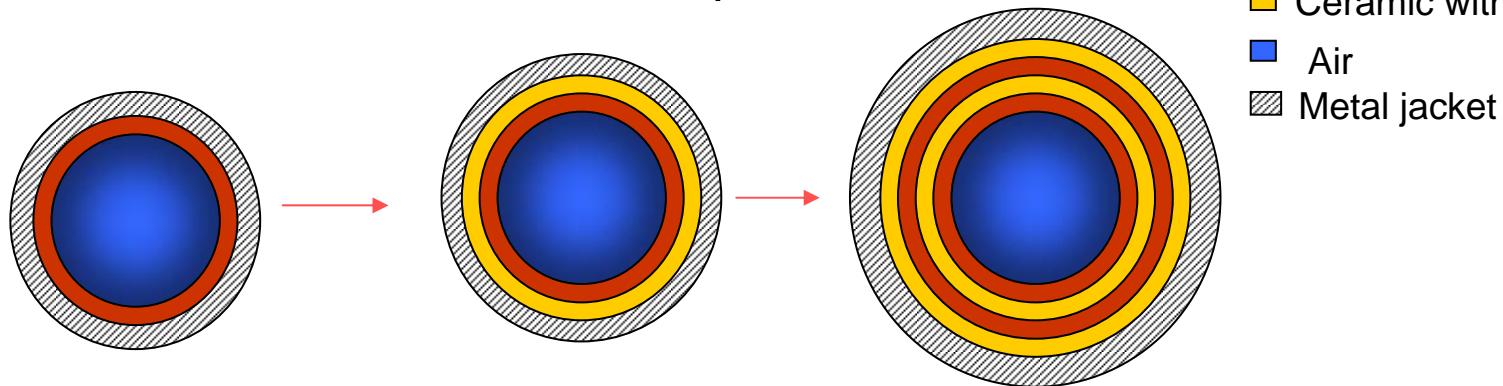
Mode Analysis

---example: 4-layer structure



Accelerating properties

---different cases comparison



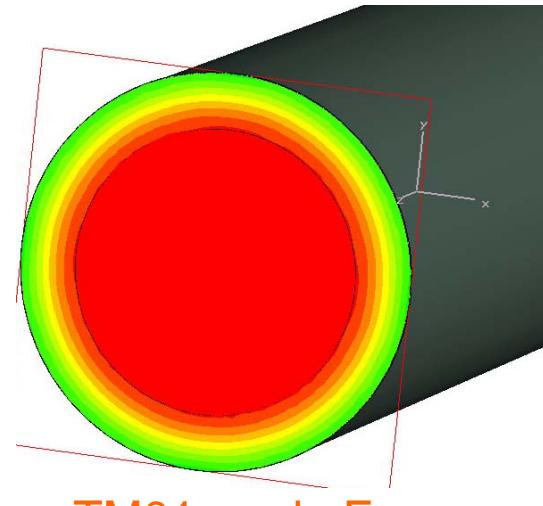
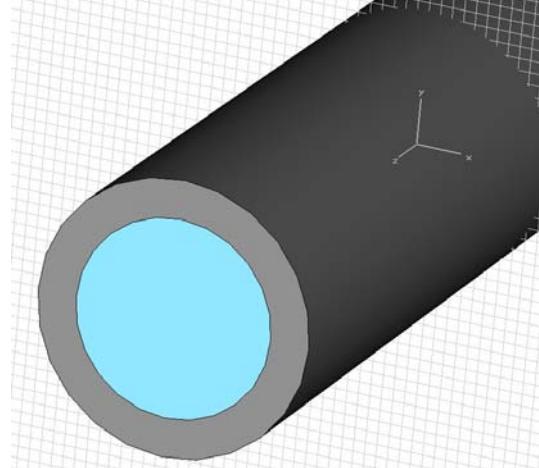
- Ceramic with high permittivity(20)
- Ceramic with low permittivity(10)
- Air
- Metal jacket

Accel. mode	radius	Cut-off freq.	Group velocity	Qw	R(MΩ/m)	R/Q (Ω/m)	Power Attn (dB/m).
One layer	b0=3mm	11.1GHz	5.5%c	2865	25.1	8756	-6.6
	b1=4.56mm						
Two layers	b0=3mm	11.04GHz	6.7%c	13454	47	3504	-1.16
	b1=5.99mm						
	b2=8.3mm						
Four layers	b0=3mm	11.03GHz	6.8%c	33451	89	2658	-0.45
	b1=5.99mm						
	b2=8.3mm						
	b3=9.8mm						
	b4=12.1mm						
NLC			5.1%c~1.1%c	9055~8093	81.2	9000~10000	-2~ ⁴⁸ ₅₀ dB

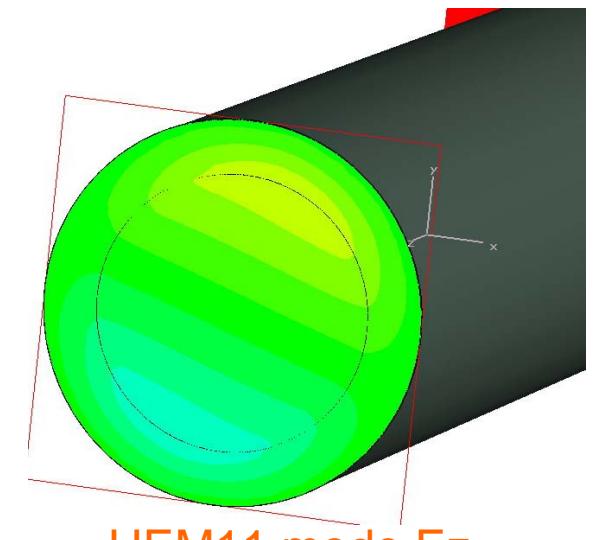
2. Transverse mode damping

[ref8]. W.Gai and C. Ho. J. Appl. Phys. 70(7). 1991, pp.3955-3957.

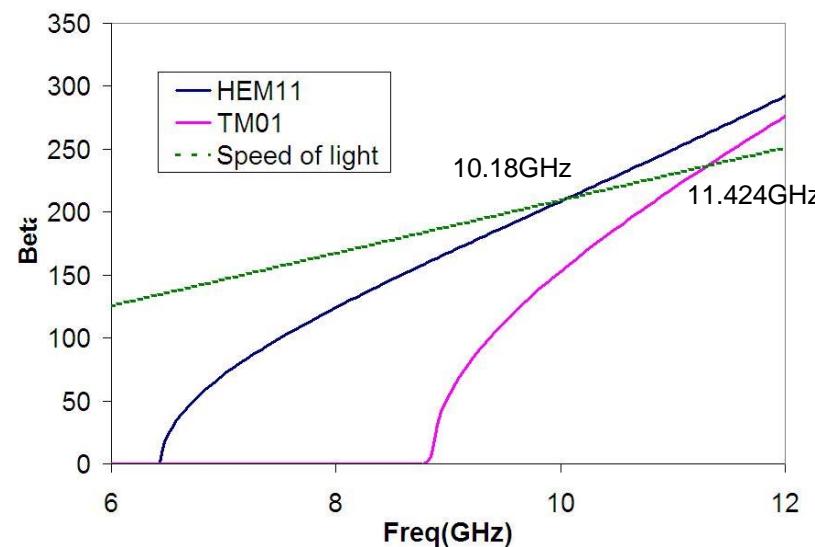
Conventional DLA structure



TM01 mode Ez

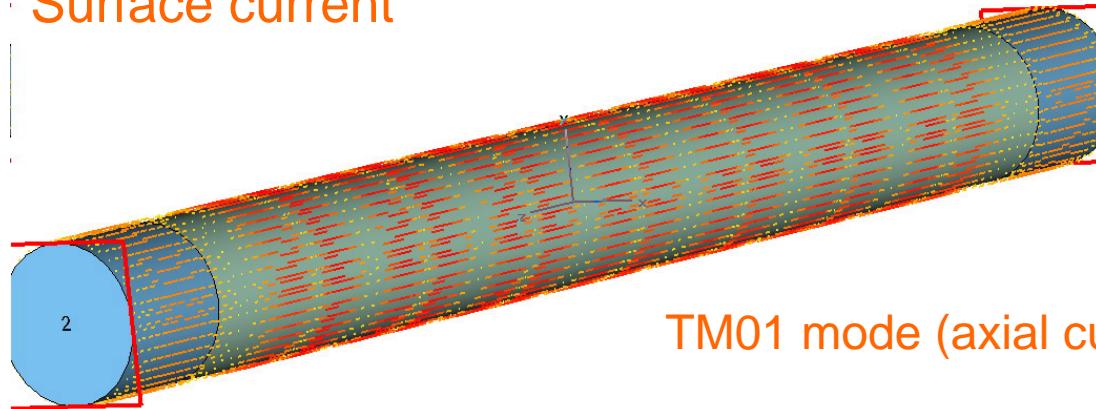


HEM11 mode Ez



Surface current distributions for different modes

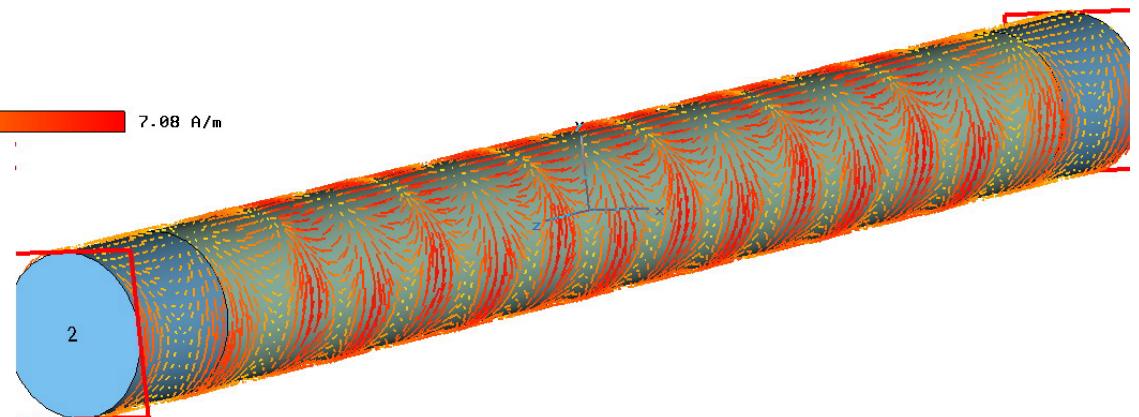
Surface current



TM01 mode (axial current only)

Type = Surface Current (peak)
Monitor = h-field (f=11.424) [1(3)]
Frequency = 11.424
Phase = 0 degrees

0 7.08 A/m



HEM11 mode (azimuthal current included)

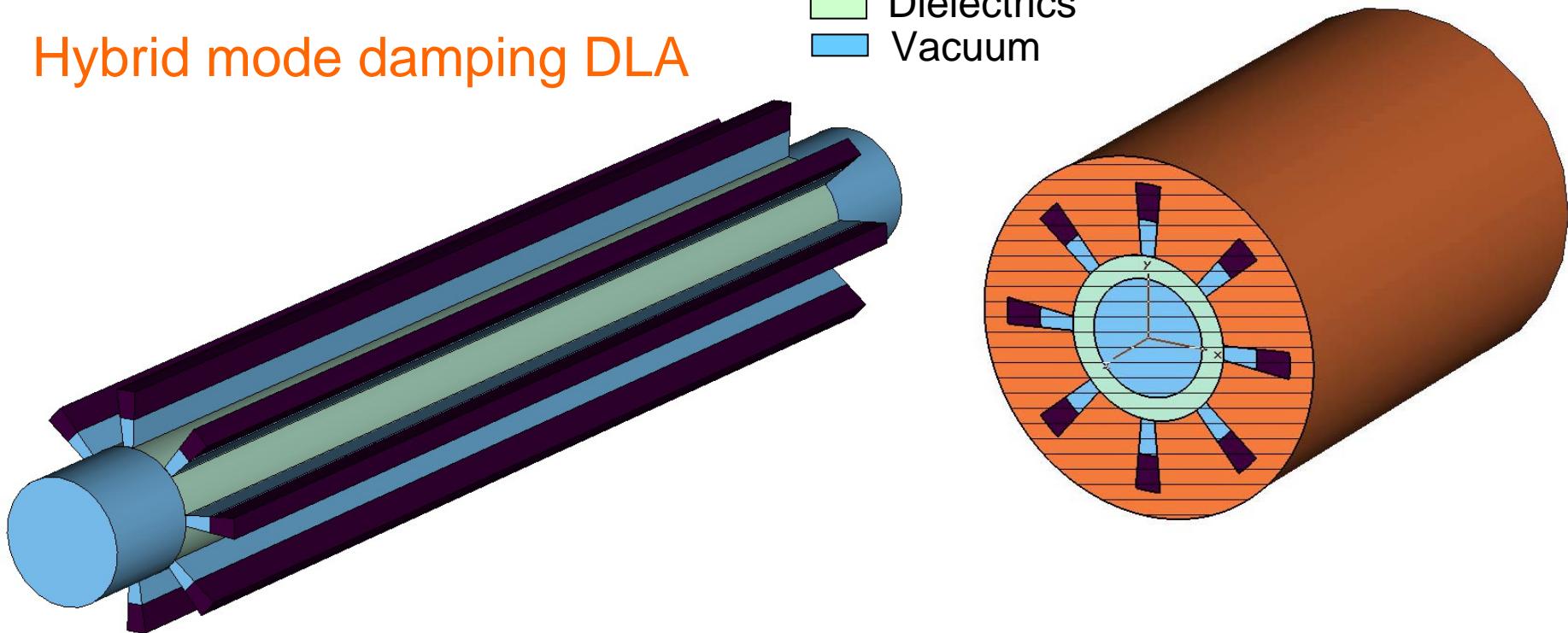
Type = Surface Current (peak)
Monitor = h-field (f=10.18) [1(1)]
Frequency = 10.18
Phase = 0 degrees

0 5.06 A/m

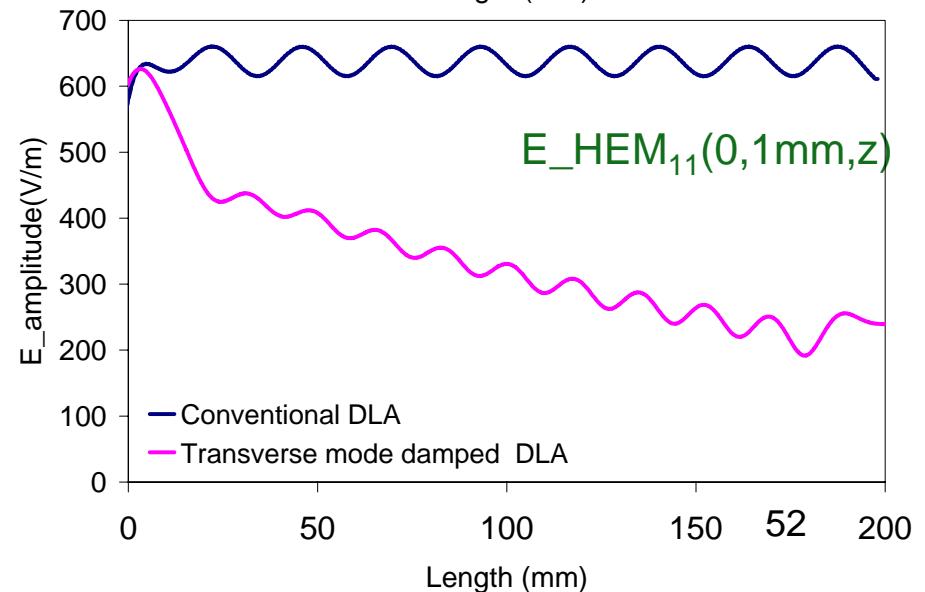
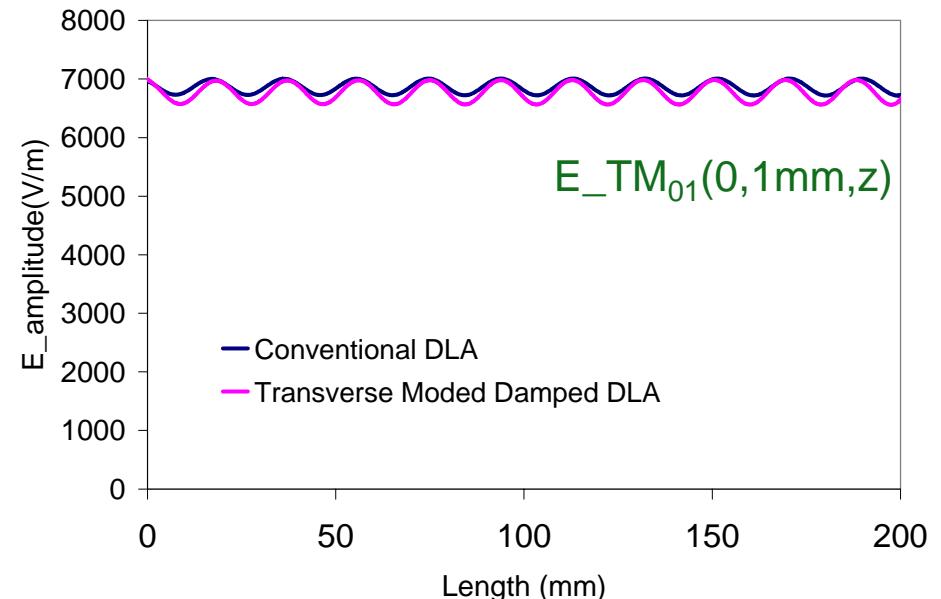
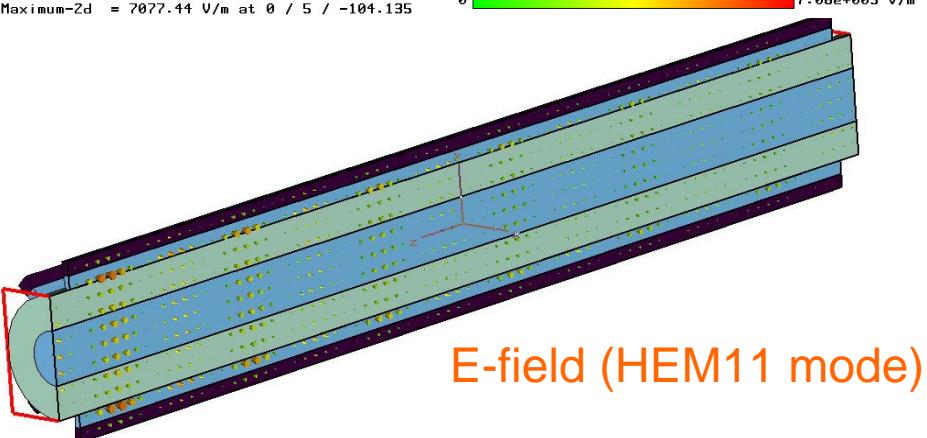
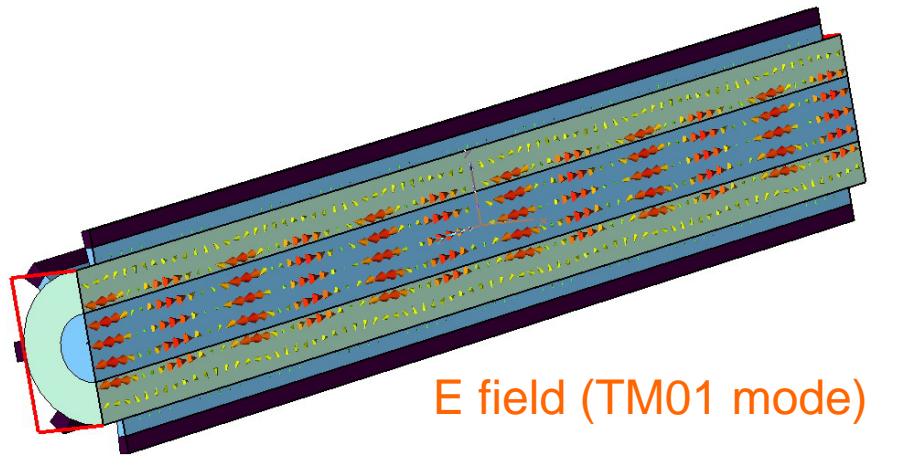
Design of transverse mode damping structure

Hybrid mode damping DLA

- [Yellow-green square] SiC($\epsilon_r \sim 13$; $\tan \delta \sim 0.22 @ 11\text{GHz}$)
- [Orange square] Copper
- [Light green square] Dielectrics
- [Light blue square] Vacuum



Simulations



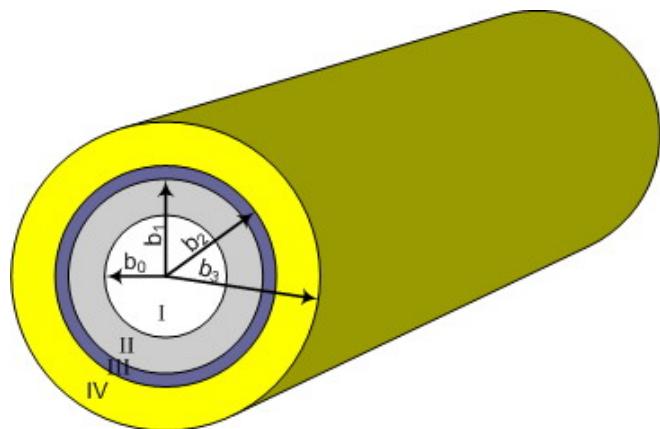
Simulated parameters

Comparison of the 7.8GHz Conventional and the Transverse mode Damped DLA structure.

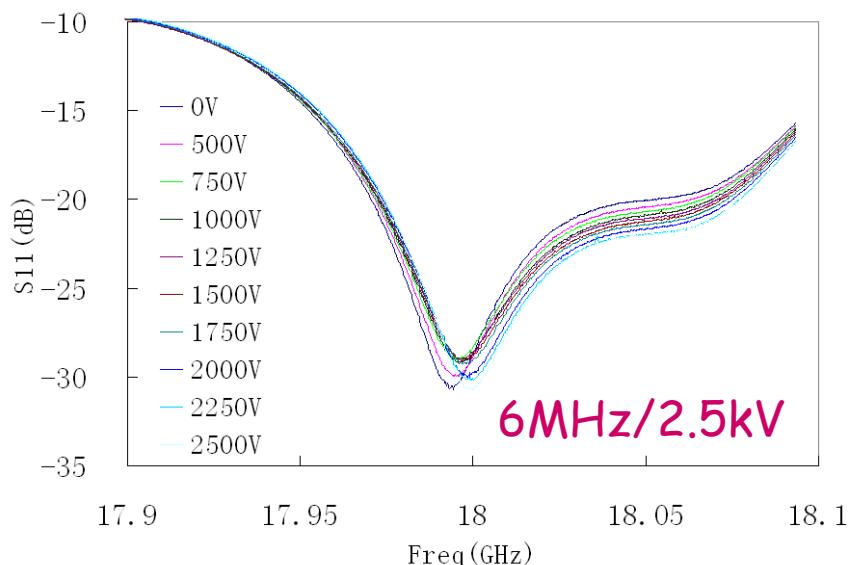
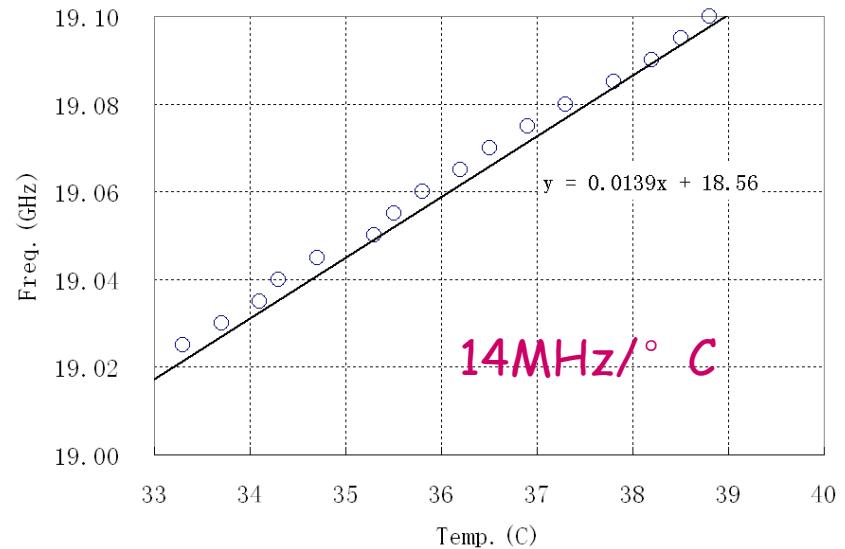
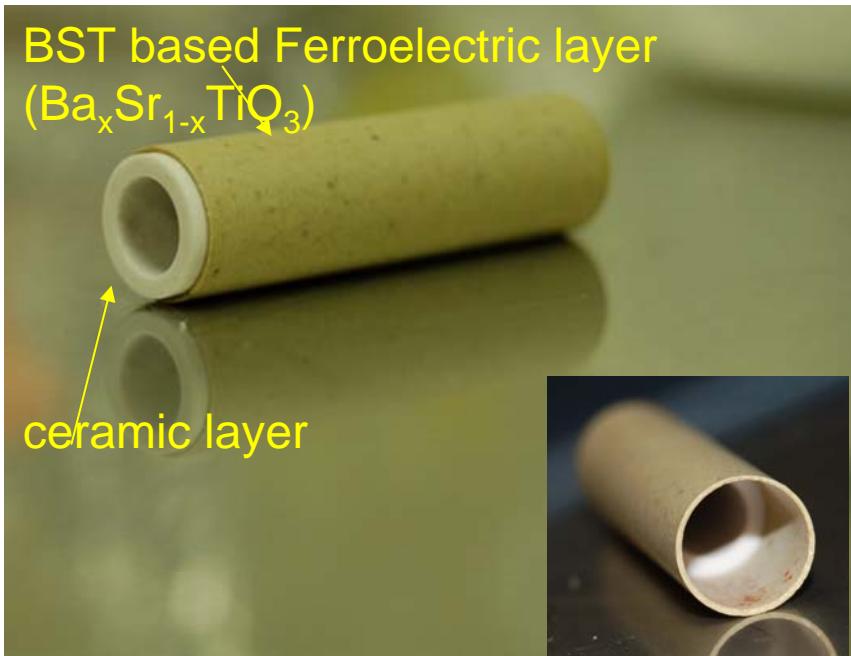
	Freq.	Q in conventional DLA structure	Q in transverse modes damped DLA structure
Accelerating mode (TM_{01})	7.8GHz	6964*	6738*
Transverse modes (HEM_{11})	6.34GHz	6866*	23*

*In the desired frequency band, SiC ($\epsilon r = 13$; $\tan \delta = 0.22$) and quartz ($\epsilon r = 3.78$; $\tan \delta = 0.5 \times 10^4$) are used in the calculations. ; Slots / circumference = 22%.

3. Frequency tuning



Configuration of the tunable DLA structure: Region I---vacuum; Region II---dielectric tube; Region III---ferroelectric tube; Region IV---copper.



4. Hybrid Dielectric-Iris-Loaded Accelerating Structure

[ref9]. P. Zou, et al. J. Appl. Phys., 2001., 90(4): 2017—2023.

Purpose: To reduce the high ratio of the peak surface electric field to the accelerating gradient for the conventional disk-loaded metal structure, meanwhile increase the shunt impedance and Q for the single layer pure dielectric-loaded accelerating structure.

